ENTRANCE TEST-2023

SCHOOL OF APPLIED SCIENCES AND TECHNOLOGY ELECTRONICS

Total Questions	:	60	Question Booklet Series	<u>A</u>
Time Allowed	:	70 Minutes	Roll No. :	

Instructions for Candidates:

- 1. Write your Entrance Test Roll Number in the space provided at the top of this page of Question Booklet and fill up the necessary information in the spaces provided on the OMR Answer Sheet.
- 2. OMR Answer Sheet has an Original Copy and a Candidate's Copy glued beneath it at the top. While making entries in the Original Copy, candidate should ensure that the two copies are aligned properly so that the entries made in the Original Copy against each item are exactly copied in the Candidate's Copy.
- 3. All entries in the OMR Answer Sheet, including answers to questions, are to be recorded in the Original Copy only.
- 4. Choose the correct / most appropriate response for each question among the options A, B, C and D and darken the circle of the appropriate response completely. The incomplete darkened circle is not correctly read by the OMR Scanner and no complaint to this effect shall be entertained.
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- A coil of inductance L=5.00 μ H and a capacitor of 5.
 capacitance C=200 pF is connected in series.
 Suppose the frequency is f=4.00 MHz. What is the net reactance?
 - (A) -j73
 - (B) j 73
 - (C) -j 199
 - (D) -j 126
- 2. The complex admittance of a certain parallel circuit is 0.010 j0.0050. What is the complex impedance of this same circuit, assuming the frequency does not change?
 - (A) 80 + j20
 - (B) 80 + i40
 - (C) 40 + i40
 - (D) 80 j 40
- 3. Which of the following is not a characteristic of an independent voltage source?
 - (A) voltage independent of magnitude of current drawn
 - (B) voltage dependent on magnitude of current drawn
 - (C) independent of direction of current flow
 - (D) can supply or receive uninterrupted energy at constant voltage
- 4. A practical voltage source can be represented by
 - (A) an ideal voltage source with its internal resistance connected in series
 - (B) an ideal voltage source with its internal resistance connected across its terminals
 - (C) by neglecting the internal resistance
 - (D) none of these

- When R = 0 in a series RLC circuit, but the net reactance is not zero, the impedance vector
- (A) always points straight up.
- (B) always points straight down.
- (C) always points straight toward the right.
- (D) None of the above is correct.
- 6. A Zener diode would most likely be found in
 - (A) the mixer in a super heterodyne receiver.
 - (B) the PLL in a circuit for detecting FM.
 - (C) the product detector in a receiver for SSB.
 - (D) the voltage regulator in a power supply.
- 7. A diode can be used as a frequency multiplier because of its
 - (A) junction capacitance.
 - (B) nonlinearity.
 - (C) avalanche voltage.
 - (D) forward break over.

Correct answer from these points:

- a. tunnel diode used for high frequency switching operations.
- b. tunnel diode uses a high doping level to provide a narrow junction.
- (A) True, False
- (B) False, False
- (C) True, True
- (D) False, True
- 9. The following is a negative differential resistance diode:
 - (A) PN Junction diode
 - (B) Zener diode
 - (C) Tunnel diode
 - (D) Schottky diode

10.	as th	ch of the following substances is sometimes used e semiconductor material in junction field-effect sistors (JFETs)?	16.
	(A)	Gallium arsenide	
	(B)	Mica	
	(C)	Glass	
	(D)	Polystyrene	
11.	A co	mmon-collector transistor circuit is often used:	17.
	(A)	to provide high gain and sensitivity over a wide	

- (A) to provide high gain and sensitivity over a wide range of frequencies.
- (B) to match a high impedance to a low impedance.
- (C) as a high-fidelity audio power amplifier.
- (D) as an oscillator at microwave frequencies.
- 12. Suppose a bipolar-transistor amplifier has a dc 18. collector input of 115 W and an ac power output of 65.0 W. What is the efficiency in percent?
 - (A) 50 %
 - (B) 5.6 %
 - (C) 5%
 - (D) 56.5 %
- 13. A twin T oscillator is commonly used for generating
 - (A) AF signals.
 - (B) High-frequency RF signals.
 - (C) Microwave RF signals.
 - (D) Powerful bursts of RF energy.
- 14. A circuit has a rms ac input voltage of 24.2 V and a 20. rms ac output voltage of 19.9 V. What is the gain in decibels?
 - (A) 1.7 dB
 - (B) -1.7dB
 - (C) 0.0849 dB
 - (D) 20 dB
- 15. The frequency at which a quartz crystal oscillator produces energy is largely dependent on :
 - (A) the load impedance.
 - (B) the physical thickness of the quartz wafer.
 - (C) the amount of resistance through the crystal.
 - (D) the power-supply voltage.

- An FET amplifier is 60 percent efficient. If the power output is 3.5 W, what is the dc drain power input?
- (A) 5.8 W
- (B) 4.0 W
- (C) 8.8 W
- (D) 7.0 W
- 7. What is the binary equivalent of decimal 29?
 - (A) 10101
 - (B) 11101
 - (C) 10111
 - (D) 11011
 - The time period of a monostable 555 multivibrator:
 - (A) RC
 - (B) 3RC
 - (C) 1.1RC
 - (D) 0.33 RC
- 19. An audio amplifier is an example of
 - (A) Digital IC
 - (B) Linear IC
 - (C) Both digital and linear IC
 - (D) None of the above
 - In voltage follower circuit the input and output voltages are:

(A)
$$V_{in}=2V$$
 and $V_{out}=3V$

(B)
$$V_{in}=10V$$
 and $V_{out}=11V$

(C)
$$V_{in} = 9V$$
 and $V_{out} = 9V$

(D)
$$V_{in} = 4V$$
 and $V_{out} = 7V$

- CMRR value of an ideal instrumentation amplifier:
 - (A) 1
 - (B) 0
 - (C) Infinity
 - (D) 0.5

- 22. Inverters are placed in series with both inputs of an 27. AND gate. Under what conditions is the output of the resulting black box high?
 - (A) If and only if both inverter inputs are high
 - (B) If and only if both inverter inputs are low
 - (C) If and only if one inverter input is high and the other is low
 - (D) Under no conditions (the output is always low) 28 .
- 23. What is the octal equivalent of binary 1010?
 - (A) 4
 - (B) 10
 - (C) 12
 - (D) There is no way to tell without more information.
- 24. What is the largest possible radix 10 number that can be represented as a six-digit binary number?
 - (A) Decimal 256
 - (B) Decimal 128
 - (C) Decimal 64
 - (D) Decimal 63
- 25. Frequency deviation in FM is:
 - (A) Change in carrier frequency to the frequency above and below the centre frequency
 - (B) Formation of side bands
 - (C) The variation of the instantaneous carrier frequency in proportion to the modulating signal
 - (D) All of the above
- 26. DeMorgan's Theorem states that, for all logical statements X and Y, where _____ is complement.
 - (A) -(X*Y) = X+Y
 - (B) X*Y = -(X+Y)
 - (C) (-X) + (-Y) = X*Y
 - (D) (-X) + (-Y) = -(X*Y)

- If you see a number represented by FF in the documentation for an electronic circuit or system, you can be certain that the number is
- (A) radix 16.
- (B) radix 10.
- (C) radix 8.
- (D) radix 2.
- A binary digital black box with two inputs, called X and Y and an output Z. If X = 0 and Y = 1, then Z = 0. In all other instances, Z = 1. Which of the following logical expressions represents the contents of the black box ?
- (A) X + (-Y)
- (B) X * (-Y)
- (C) X (*Y)
- (D) X = (-Y)
- 29. Suppose a logic circuit has four inputs W, X, Y, and Z. How many possible input combinations are there?
 - (A) 4
 - (B) 8
 - (C) 16
 - (D) 32
- 60. What can be done to minimize the capacitance of the P-N junction in a semiconductor diode, thereby making the component effective as a high-speed RF switch?
 - (A) The surface area of the P-N junction can be maximized.
 - (B) A layer of intrinsic semiconductor can be placed between the P- and N-type materials.
 - (C) The frequency of the applied signal can be made as high as possible.
 - (D) The diode can be forward- biased with a high voltage.

- 31. Notch filter is a:(A) Band pass filter
 - (B) Band stop filter
 - (C) Low pass filter
 - (D) High pass filter
- 32. What is the wavelength if the frequency is 4MHz?
 - (A) 75 meters
 - (B) 75 km
 - (C) 75 cm
 - (D) 75 mm
- 33. Signal attenuation, or degradation, exists in all media of wireless transmission. It is proportional to the :
 - (A) the distance between the transmitter and receiver
 - (B) difference of the distance between the transmitter and receiver
 - (C) square of the distance between the transmitter 39.
 - (D) summation of the distance between the transmitter and receiver
- 34. TCP stands for:
 - (A) Transmission Control Protocol
 - (B) Transmission Capture Protocol
 - (C) Transmission Control Procedure
 - (D) Transistor Capacitor Power
- 35. A receiver that responds to a desired signal, but not to another signal very close by in frequency, has good
 - (A) Sensitivity.
 - (B) Noise figure.
 - (C) Dynamic range.
 - (D) Selectivity.
- 36. The domain name system (DNS) is chiefly used to translate hostnames into:
 - (A) Alphabetical address
 - (B) Numeric IP addresses
 - (C) Analog address
 - (D) All of the above

- 37. A continuously variable signal can be recovered from a signal having only a few discrete levels or states by means of:
 - (A) a ratio detector.
 - (B) a D/A converter.
 - (C) a product detector.
 - (D) an envelope detector.
- 38. An AM super heterodyne receiver with IF of 455 kHz is tuned to the carrier frequency of 1000 kHz. The image frequency is:
 - (A) 545 kHz
 - (B) 1 MHz
 - (C) 1455 kHz
 - (D) 1910 kHz
- 39. In FM signal with a modulation index mf is passed through a frequency Tripler. The wave in the output of the Tripler will have a modulation index of:
 - (A) mf
 - (B) 3mf
 - (C) mf/3
 - (D) mf/9
- 0. The maximum power efficiency of an AM modulator is:
 - (A) 25%
 - (B) 33%
 - (C) 50%
 - (D) 100%
- 41. Which of the following modes is used to send image data over telephone lines?
 - (A) On/offkeying
 - (B) Fax
 - (C) AM
 - (D) Product detection

- 42. READY signal used in an intel 8085 microprocessor 47. is:
 - (A) To indicate to user that the microprocessor is working and is ready for use.
 - (B) To provide proper WAIT states when the microprocessor is communicating with a slow peripheral device.
 - (C) To slow down a fast peripheral device so as to communicate at the microprocessor's device.
 - (D) None of the above.
- 43. The 8085 has six general-purpose registers to store 8-bit data; these are identified as:
 - (A) A, C, D, E, H, and L
 - (B) B, C, D, E, H, and I
 - (C) B, C, D, E, H, and L
 - (D) B, C, D, E, F, and L
- 44. The ALU includes five flip- flops, which are set or reset after an operation according to data conditions of the result in the accumulator and other registers. These flags are:
 - (A) Z, CY, S, P and AC
 - (B) A, CY, S, P and AC
 - (C) F, CY, S, P and C
 - (D) W, CY, S, P and A
- 45. Immediate addressing in 8085 example is:
 - (A) MVI data, R
 - (B) MVI R, data
 - (C) MOV R, data
 - (D) MOVE R, data
- 46. Trap interrupt is a non-maskable restart interrupt; it has the priority of any interrupt.
 - (A) Lowest
 - (B) Medium
 - (C) Less
 - (D) Highest

- Which one is not correct in 8085 microprocessors?
- (A) RAC Rotate the accumulator to Carry. Bit 0 goes to bit 7 AND the Carry flag
- (B) RAR Rotate the accumulator right through the carry. Bit 0 goes to the Carry and carry goes to bit 7.
- (C) RLC Rotate the accumulator left. Bit 7 goes to bit 0 and the carry flag.
- (D) RAL Rotate the accumulator left through the carry. Bit 7 goes to the carry and carry goes to bit 0.
- 48. The 8085 has 16 address lines. So, it can address a total of memory locations:
 - (A) 65K
 - (B) 64K
 - (C) 128K
 - (D) 16K
- 49. The 8051 is an:
 - (A) 8-bit microcontroller with 8-bit data bus and 16-bit address bus.
 - (B) 16-bit microcontroller with 16-bit data bus and 16-bit address bus.
 - (C) 16-bit microcontroller with 8-bit data bus and 8-bit address bus.
 - (D) 8-bit microcontroller with 8-bit data bus and 8-bit address bus
 - The 8051 has:
 - (A) 3 internal interrupts, 3 external interrupts.
 - (B) 4 internal interrupts, 2 external interrupts.
 - (C) 2 internal interrupts, 2 external interrupts.
 - (D) 3 internal interrupts, 2 external interrupts.

51. The interrupt has highest priority in 8051 56. Integrating instruments among the following is: microcontrollers: (A) Ammeters (A) IE0 (B) Voltmeters (B) TF0 (C) Wattmeter (C) IE1 (D) Watt-hour meters (D) TF1 In an enhancement-mode MOSFET, 52. In addressing of 8051 The storage of addresses that (A) the channel conducts fully with zero gate bias. can be directly accessed is: (B) the channel conducts partially with zero gate (A) external data RAM bias. (B) internal data ROM (C) the channel conducts ac but not dc. (C) internal data RAM and SFRS (D) the channel does not conduct with zero gate bias. (D) external data ROM and SFRS The high input impedance of a MOSFET makes this 53. For measuring a very high resistance we should use: type of device ideal for use in (A) Kelvin's double bridge (A) weak-signal amplifiers. (B) Wheatstone bridge (B) high-power oscillators. (C) Meggar (C) high-current rectifiers. (D) None of the above (D) antenna tuning networks. 54. An ammeter shunt is useful because: 59. A significant difference between MOSFETs and JFETs is the fact that: (A) It increases meter sensitivity. (A) MOSFETs can handle a wider range of gate (B) It makes a meter more physically rugged. bias voltages. (C) It allows for measurement of a wide range of (B) MOSFETs can deliver greater output power. currents. (C) MOSFETs are more rugged. (D) It prevents overheating of the meter. (D) MOSFETs last longer. The main advantage of a FETVM over a conventional 55. voltmeter is the fact that the FETVM: 60 An optocoupler consists of:

(A) Can measure lower voltages.

(B) Draws less current from the circuit under test.

(C) Can withstand higher voltages safely.(D) Is sensitive to AC as well as to DC.

(A) two Zener diodes back-to-back.

(B) an LED and a photodiode.

(C) two NPN transistors in series.

(D) an NPN transistor followed by a PNP transistor.

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ENTRANCE TEST-2020

SCHOOL OF APPLIED SCIENCES AND TECHNOLOGY

ELECTRONICS

Question			
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Total Questions :

60

Time Allowed

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JJ-327-C

1 *** Turn over

1	A 4-bit parallel full adder without any carry requires:	initial 5.	A memory system has a total of 8 memory chips, each with 12 address lines and 4 data lines. The total size of the memory system is:
	(A) 8 half adders and 4 OR gates		(A) 32 Kbytes
20	(B) 8 half adders and 3 OR gates		(B) 48 Kbytes
	(C) 7 half adders and 4 OR gates(D) 7 half adders and 3 OR gates		(C) 128 Kbytes
			(D) 384 Kbytes
2.	Each cell of a Random Access Memory c (A) 6 MOS transistors	6.	In 8085 the number of output ports in the peripheral mapped I/O is restricted to :
	(B) 4 MOS transistors and 2 capacito	ors	(A) 128
	(C) Two 2-input NOR and one X-NO)R gates	(B) 256
	(D) XOR gates and shift registers		
3.	The total number of operation co instructions in the 8085 microprocessor in	nstruction	(C) 512(D) None of the above
	set are and respect	tively. 7.	Different ways of making operands available in 8085 are called:
	(A) 74, 244 (B) 72, 244		(A) Instruction Fetch
	(C) 74, 246		(B) Addressing Modes
	(D) 72, 246		(C) Memory Fetch
		0005	
4	The following program is run on microprocessor.		(D) Data Fetch Which of the following techniques is preferable
	Memory Address in Hex Instruction LXI S	etions 8. SP, 1000	for transferring large amount of data to and from the memory in a short time?
	2003 PUSH		(A) Programmed I/O
	2004 PUSH	2050	(B) Interrupt driven I/O
	2005 2008 POP		(C) DMA
	2009 HALT		(D) None of these
	At the completion of execution of p	rogram the	
	program counter contains an pointer contains	d the stack	How are the bits of the register PSW affecte if we select Bank2 of 8051 ?
	(A) 1025, 0CCF		(A) PSW.5=0 and PSW.4=1
	(B) 1025, 0FFC		(B) PSW.2=0 and PSW.3=1
	(C) 2050, 0CCF		(C) PSW.3=1 and PSW.4=1
	(D) 2050, 0FFC		(D) PSW.3=0 and PSW.4=1

10.	Number of I/O ports in the 8051 microcontroller 15. are: (A) 3 ports	A signal x(t), having peak to peak signal swing 2.048V, is sampled. The sampling rate is 8000 samples/sec. Each sample is coded as an
	(B) 4 ports	11 bit linear PCM code. The step size is:
	(C) 5 ports	(A) 4 mV
	(D) 4 ports with last port having 5 pins	(B) 2 mV
		(C) 0.5 mV
11.	A 1.0 KHz square wave signal is passed through a ideal filter having cut-off at 4500 Hz. It is	(D) 1 mV
	used to amplitude modulate a carrier of 10 KHz. 16. The spectral width of modulated signal is:	To separate channels in a TDM receiver, it is necessary to use:
	(A) 8.0 KHz	(A) AND gates
	(B) 9.0 KHz main main bin (A)	(B) Band pass filters
	(C) 4.5 KHz gning? (a)	(C) Differentiation
	(D) 10 KHz	(D) Integration
12.	The Carlson bandwidth of an FM system is 17. 170 kHz when the frequency deviation is 17. 75 kHz. The modulation index β is:	is done in order to :
		(A) Enhance the information transmission rate
	(A) 15	(B) Reduce the transmission errors
	(B) 2.29 (C) 7.5 (D) 10 100 (C)	(C) Conserve the transmitted power
	(D) None of the above	(D) Facilitate clock recovery in the receiver
13	18.	Which of the following requires a synchronizing signal?
	(A) SSB/SC	(A) Single channel PPM system
	(B) DSB-AM	(B) PAM
	(C) SSB-Pilot carrier	
	(D) DSB/SC	(C) DM(D) All of the mentioned
14	A signal $x(t) = A \sin \omega t$ is affected by noise $n(t)$. N represents the noise power. The SNR of 19	A, it is a tips hole to be a second and a long
	a system is:	(A) DSB-SC systems
	(A) A^2/N	(B) FSK systems
	(B) 2A ² /N	(C) Pulse width modulation
	(C) $A^2/(2N)$	(D) Pulse code modulation
	(D) None of above	
J.	J-327-C 3	[Turn over

20,	usir		25.	-	gets propagated through networks and unologies like SMS, Bluetooth, wireless
		Low pass filter			lium, USB's and infrared to affect mobile
	(B)	High pass filter		pho	nes.
	(C)	Band pass filter		(A)	Worms
	(D)	Band stop filter		(B)	Antivirus
21.	A c	ordless telephone using separate frequencies		(C)	Malware
		transmission in base and portable units is wn as:		(D)	Multimedia files
	(A)	Duplex arrangement	26.	In m	ajority of instruments, damping is provided
	(B)	Half duplex arrangement		by:	
	(C)	Either (A) or (B)		(A)	Fluid friction
	(D)	Neither (A) nor (B)		(B)	Spring
22.	Whi	ich of the following memory devices stores		(C)	Eddy currents
	info	rmation such as subscriber's identification aber in GSM?		(D)	All of the above
	(A)	Register	27.	A ur	niversal RLC bridge uses :
	(B)	Flip flop			Maxwell bridge configuration for
	(C)	SIM			measurement of inductance and De Santy's
	(D)	SMS			bridge for measurement of capacitance
23.		manages the switching function in GSM.			Maxwell Wein bridge configuration for measurement of inductance and De Santy's
	(A)	BSS			bridge for measurement of capacitance
	(B)	NSS			Maxwell Wein bridge configuration for
	(C)	OSS			measurement of inductance and Wein bridge
	(D)	MSC			for measurement of capacitance None of the above
24.	Wha	t is frequency reuse ?		(D)	Trone of the above
		Process of selecting and allocating channels			citance sensor can measure very small
		Process of selection of mobile users			acement. It can be formed by varying:
		Process of selecting frequency of mobile			Separation
		equipment		(B)	
	(D)	Process of selection of number of cells			Permittivity
		· ·		(D)	Either (A) or (B) or (C)
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- during the process of taking the repeated measurements then the random errors can be eliminated by:
 - (A) Calculating the mean of the number of repeated measurements
 - (B) Calculating the median of the number of repeated measurements
 - (C) Calculating the sum of the numbers of repeated measurements
 - (D) Either (A) or (B)
- 30. LVDT which is an instrument for the measurement of displacement, works on the principle of:
 - (A) Linear inductance
 - (B) Non-linear inductance
 - (C) Mutual inductance
 - (D) Linear capacitance
- 31. Q factor of a series resonance circuit can be increased by using:
 - (A) A coil of large inductance, and small Ohmic resistance
 - (B) A coil of large inductance and large Ohmic resistance
 - (C) A coil of small inductance and large Ohmic resistance
 - (D) A coil of small inductance, and small Ohmic resistance
- 32. Superposition theorem is applicable to:
 - (A) Power only
 - (B) Current only
 - (C) Voltage only
 - (D) Current and Voltage both
- 33. At t = 0+ with zero initial condition, which of the following act as an open circuit?
 - (A) Inductor
 - (B) Capacitor
 - (C) Resistor
 - (D) All of the above

- 29. If the quantity to be measured remains constant 34. The current through a branch in a linear network is 2A when the input source voltage is 10 V. If the voltage is reduced to 1V and the polarity is reversed, the current through the branch is:
 - (A) 2.0
 - (B) -0.2
 - (C) + 0.2
 - (D) + 2.0
 - 35. dBm is a:
 - (A) Unit of Power
 - (B) Unit of Voltage
 - (C) Ratio of Power
 - (D) None of the above
 - 36. Mobility of holes in intrinsic Si is
 - (A) $0.048 \text{ m}^2/\text{Vs}$
 - (B) $0.135 \text{ m}^2/\text{Vs}$
 - (C) $1350 \text{ m}^2/\text{Vs}$
 - (D) $480 \text{ m}^2/\text{Vs}$
 - The reverse saturation current I_{co} of Si diode varies as:
 - (A) T^2
 - (B) T^3
 - (C) $T^{1/2}$
 - (D) $T^{3/2}$
 - 38. The tunnel diode:
 - (A) Has a tiny hole through its centre to facilitate tunneling
 - (B) Is a point contact diode with a very high value of reverse resistance
 - (C) Uses a high doping level to provide a narrow iunction
 - (D) None of the above

- 39. For a BJT, D_E , D_B , and D_C are doping 45. A Darlington amplifier is characterized by : concentrations for emitter, base, and collector respectively then:
 - $(A) D_C > D_F > D_R$
 - (B) $D_E > D_C > D_R$
 - (C) $D_E > D_B > D_C$
 - (D) $D_C > D_B > D_F$
- 40. The voltage divider bias is used to make the Q-point:
 - (A) Independent of β
 - (B) Independent of V_{BE}
 - (C) Dependent of β
 - (D) None of the above
- 41. The h- parameters of a BJT are:
 - (A) Dependent on R,
 - (B) Dependent on I_{CO}
 - (C) Independent of I_{CO}
 - (D) Constant
- 42. The transition cut-off frequency f_T at which the magnitude of short circuit current gain of transistor in CE configuration is:
 - (A) Half of the mid-band gain
 - (B) One-tenth of the mid-band gain
 - (C) Unity
 - (D) 100
- 43. Dynamic transfer curve of an amplifier is a plot of:
 - (A) Output voltage vs. input current
 - (B) Output current or voltage vs. input excitation
 - (C) Output current vs. input current
 - (D) None of the above
- 44. Low frequency response of amplifiers is mainly limited by:
 - (A) Coupling capacitors
 - (B) Bypass capacitors
 - (C) Biasing circuit
 - (D) Input and Output capacitors

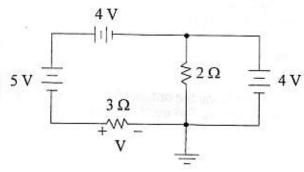
- - (A) Very high voltage and current gains
 - (B) Very high input resistance and current gains
 - (C) Very low resistance and current gain
 - (D) None of the above
- 46. Cross-over distortion in Class-B push-pull amplifiers can be overcome by:
 - (A) Operating it as Class-C
 - (B) Operating it as Class-AB
 - (C) Using a low leakage transformer
 - (D) None of the above
- 47. Why are R-C oscillators unsuitable for radio frequency applications?
 - (A) At higher radio frequencies capacitors required have non-practical values
 - (B) Resistors and capacitors get heated up at higher frequencies
 - (C) Resistors cause tremendous power loss at higher frequencies
 - (D) None of the above
- 48. The frequency at which the differential gain in Op Amps is zero dB is called:
 - (A) Unity gain cross-over frequency
 - (B) Cross over frequency
 - (C) Zero-dB frequency
 - (D) Cut-off frequency
- 49. In cascade tuned amplifier, the impedance transformation is achieved through:
 - (A) Tapping of inductor of the tank circuit
 - (B) Tapping of capacitor of the tank circuit
 - (C) Tapping both of the above (A and B)
 - (D) None of the above

- 50. A differentiator is rarely used in analog computers 55. The efficiency of an LED for generating light is because:
 - (A) It reduces the gain
 - (B) It decreases the output of the amplifier
 - (C) It amplifies noise, drift, and other unwanted disturbances
 - (D) None of the above
- 51. For an Op-amp with negative feedback, the output is:
 - (A) Equal to the input
 - (B) Increased
 - (C) Fed back to the inverting input
 - (D) Fed back to the non-inverting input
- 52. For operating a p-channel MOSFET, the gate is applied a:
 - (A) Positive potential (for enhancement mode)
 - (B) Negative potential (for depletion mode)
 - (C) Negative potential (for enhancement mode)
 - (D) None of the above
- 53. An SCR may be turned off by:
 - (A) By reducing its anode to cathode voltage
 - (B) By removing the gate voltage pulse
 - (C) By reducing the current below the holding value
 - (D) None of the above
- 54. In case a reverse biased photodiode is kept in dark condition, the current flowing through the device corresponds to:
 - (A) Maximum value of current which can flow through the device
 - (B) Value of reverse saturation current
 - (C) Normal value of current
 - (D) Zero

- directly proportional to the:
 - (A) Temperature
 - (B) Voltage applied
 - (C) Level of doping used
 - (D) Current injected
- 56. Which of the following is a unique property of laser ?
 - (A) Directional
 - (B) Speed
 - (C) Coherence
 - (D) Wavelength
- 57. The output of a 2-input logic gate is 1 when all its inputs are at logic 0. The gate is:
 - (A) A NAND or an EX-OR gate
 - (B) A NOR or an EX-OR gate
 - (C) An AND or an EX-NOR gate
 - (D) None of the above
- 58. When signed numbers are used in binary arithmetic, then which of the following notations would have unique representation for zero?
 - (A) Sign-magnitude
 - (B) 1's complement
 - (C) 2's complement
 - (D) 9's complement
- 59. A 4-bit modulo 16 used JK flip flop. If the progression delay of each flip flop is 50 ms, the maximum clock frequency is equal to:
 - (A) 800 MHz
 - (B) 12.5 MHz
 - (C) 4 MHz
 - (D) None of the above
- 60. If a counter having 10 flip flops is initially at 0. what count will it hold after 2060 pulses?
 - (A) 0000001100
 - (B) 0000011100
 - (C) 0000011000
 - (D) 0000001110

JJ-327-C

- Which parameters are also called short circuit 6. parameters?
 - (A) z
 - (B) y
 - (C) h
 - (D) None of the above
- 2. An ideal source consists of 5 V in series with $10 \text{ k}\Omega$ resistance. The current magnitude of equivalent current source is:
 - (A) 2 mA
 - (B) 3.5 mA
 - (C) 0.5 mA
 - (D) None of the above
- The voltage 'V' across 3Ω resistor in figure is equal 3. to:



- (A) 3 V
- (B) −3 V
- (C) 5 V
- (D) 4 V
- A generator of internal impedance 'Zi' deliver maximum power to a load impedance, Z1 only if:
 - (A) Z, < Z</p>
 - (B) $Z_1 > Z_2$
 - (C) $Z_1 = Z_2$
 - (D) $Z_1 = 2Z_1$
- In the depletion region of a pn junction, there is a 12. shortage of:
 - (A) Acceptor Ions
 - (B) Holes and Electrons
 - (C) Donor Ions
 - (D) None of the above

- The ripple factor of a half-wave rectifier is:
 - (A) 2
 - (B) 1.21
 - (C) 2.5
 - (D) 0.48
- The frequency of a full-wave signal is equal to:
 - (A) Twice the line frequency
 - (B) Equal to the line frequency
 - (C) One-half of the line frequency
 - (D) One-fourth of the line frequency
- Avalanche breakdown in a semiconductor take place:
 - (A) When forward current exceeds a certain valu
 - (B) When potential barrier is reduced to zero
 - (C) When reverse bias exceeds a certain value
 - (D) When forward bias exceeds a certain value
- The emitter of a transistor is_ doped.
 - (A) Lightly
 - (B) Heavily
 - (C) Moderately
 - (D) None of the above
- 10. $I_c = \alpha I_E + ____$
 - (A) I_B
 - (B) I_{CEO}
 - (C) I_{CBO}
 - (D) βI_B
- The phase difference between the input and output voltages of a transistor connected in common collector arrangement is:
 - (A) 180°
 - (B) 270°
 - (C) 90°
 - (D) 0°
- The constant-current region of a JFET lies between:
 - (A) Cut off and saturation
 - (B) Cut off and pinch-off
 - (C) 0 and I_{DSS}
 - (D) Pinch-off and breakdown

55.

13.	The decimal equivalent of hex number (1A53) ₁₆ is:	20.	The commercially available 8-input multiplexer
	(A) (6793) ₁₀		integrated circuit in the TTL family is:
	(B) (6739) ₁₀		(A) 7495
	(C) (6973) ₁₀		(B) 7490
	(D) (6379) ₁₀		(C) 74151
14.	A ring counter consisting of five Flip-Flops will		(D) 74154
	have:	21.	How many address bits are required to represent
	(A) 5 states		4K memory?
	(B) 10 states		(A) 5 bits
	(C) 32 states		(B) 12 bits
	(D) Infinite states		(C) 8 bits
15.			(D) 10 bits
	(A) (0101110) ₂	22	In the a.c. equivalent circuit of a transistor amplifier,
	(B) (0111110) ₂	22.	the capacitors are considered:
	(C) (0110010) ₂		200
	(D) (0010011) ₂		(A) Short
16.	When simplified with Boolean Algebra $(x+y)(x+z)$		(B) Open
	simplifies to:		(C) Partially Open
	(A) x		(D) None of the above
	(B) x + x(y + z)	23.	The purpose of emitter capacitor (i.e. capacitor
	(C) x(1+yz)		across R _e) is to:
	(D) x+yz		(A) Avoid voltage gain drop
17.			(B) Forward bias the emitter
	their preceding number by single bit is:		(C) Reduce noise in the amplifier
	(A) Binary code		(D) None of the above
	(B) BCD code	24.	
	(C) Excess-3 code	27.	current flows for 160 degrees of the input signal,
	(D) Gray code		then it is operation.
18.]		(A) Class A
	(A) TIL		1805 sas ma
	(B) ECL		(B) Class C
	(C) CMOS		(C) Class B
10	(D) PMOSIf the input to T-flip flop is 100 Hz signal, the final		(D) Class AB
19	output of the three T-flip flops in cascade is:	25.	. Which coupling has the best frequency response?
			(A) Direct
	1. ft		(B) RC
	(B) 300 Hz (C) 33.3 Hz		(C) Transformer
			(D) Transistor
	(D) 12.5 Hz		A HILP

5:

26	C. C. C.	gain without feedback and feedback factor are A	32	. Th	ne resistance of a moving-coil instrument i	s 10 O
	and	β respectively, then gain with negative feedback		an	d gives full-scale deflection at 10 mA. Ca	lculate
		riven by:		the	e resistance of the shunt required to conv	ert the
	10000	A/(1-Aβ)		ins	trument to give full-scale deflection when the	circuit
	(B)			cur	rrent is 5A:	10127838955
		(1-Aβ)/A		(A)) 0.02004 Ω	
		$A/(1+A\beta)$		(B)	0.020004 Ω	
27.	. The	e frequency of oscillation is L and C in an		(C)	20.4 Ω	
	LC	oscillator.		(D)	2.04 Ω	
	(A)	Inversely proportional to square root of	33.	Wł	nat is the typical input resistance of	of the
	(B)	Directly proportional to square root of		μΑ	741 op-amp when measured under open l	loop?
	(C)			(A)		ŧ.
	(D)			(B)	3 ΜΩ	
28.	Giv	en three amplifiers with each having a gain of 10		(C)	$2 M\Omega$	
	dB a	and are connected in cascade. How much is the		(D)		
		rall gain in dBs?	34.	Wh	at is the most popular IC used in timing circ	cuits?
	(A)	1000		(A)		
	(B)	100		(B)	741	
	(C)	30		(C)	LM317	
	(D)	20		(D)	LM340	
29,	With	given full-scale deflection currents, which meter	35.	And	op-amp circuit that has its output tied direc	tly to
	is the	e most sensitive ?		the i	nverting terminal is called a:	- Pi
	(A)	10 mA		(A)	Current follower	
	(B)	I mA		(B)	Inverting amplifier	
	(C)	1 A		(C)	Non-inverting amplifier	
	(D)	1 μΑ		(D)	Voltage follower	
30.	Ana	mmeter's ideal resistance should be:	36.	Wha	at is the slew rate of a 741 operati	onal
		Zero		ampl	lifier?	
	(B)	Unity		1000	1 V/ms	+:
		Infinite		(B)	0.5 V/ms	P
		The same as the circuit's resistance		(C)	1 V/μs	
31.		force in analog instance 11111		(D)	0.5 V/μs	- 1
	movi	ng system to rest in its final position is:	37.	Wha	t element of a CRT releases electrons w	hen
		Damping force			d indirectly by a filament?	- 1
		Controlling force			Cathode	- 1
		Deflection force			Grid	
	(3)	None of the above			Anode	- 1
	(D)	None of the above)	(D)	Phosphor screen	- 1

Some of the pins of an 8085 CPU and their functions 38. Which part of the following is not a basic part of a 45. are listed below. Identify the correct answer that CRT? matches the pins to their respective functions: (A) Electron Gun RST 7.5 Selects IO or memory Ρ. (B) Focusing and accelerating elements Demultiplexes the address (C) Horizontal and vertical deflecting plates . Q. Hold IO/M and data bus R. (D) Sawtooth Generator S. ALE Is a vectored interrupt 39. The bridge used to measure high-Q inductances Facilitates direct memory (Q > 10) is: access (A) Wheatstone bridge (A) P-3, Q-2, R-1, S-4 (B) Wien bridge (B) P-4, Q-1, R-2, S-3 (C) Hay bridge (C) P-3, Q-4, R-1, S-2 (D) Schering bridge (D) P-2, Q-3, R-4, S-1 40. Kelvin double bridge is used to measure: 46. How many instructions does microprocessor 8085 (A) Capacitance (B) Low-value resistance have? (C) Low-Q inductance (A) 255 (D) High value resistance (B) 256 41. The first microprocessor built by the Intel Corporation (C) 246 was called: (D) 250 (A) 8008 What is the vectored address of interrupt RST 5.5? (B) 8080 (A) 0034 H (C) 4004 (B) 0024 H (D) 8800 (C) 0036 H The number of output pins of a 8085 microprocessor (D) 002C H are: 48. If the status of the control lines S, and So is low, then (A) 40 8085 microprocessor is performing: (B) 19 (A) Reset operation (C) 21 (B) Hold operation (D) 27 (C) Halt operation 43. Which signals of 8085 microprocessor is used to insert wait states? (D) Interrupt acknowledge (A) READY 49. Modulation is done in: (B) ALE (A) Transmitter (C) HOLD (B) Radio receiver (D) INTR (C) Between transmitter and radio receiver 44. Which of the following flag conditions is not available (D) None of the above in 8085 microprocessor? In an AM wave, useful power is carried by: (A) Zero Flag (A) Carrier (B) Parity Flag (B) Sidebands (C) Overflow Flag

(D) Auxiliary Carry Flag

(C) Both sidebands and carrier

(D) None of the above

Consider the following Amplitude Modulated (AM)
 signal,

 $X_{AM}(t) = 10(1 + 0.5 \sin 2\pi f_m t) \cos 2\pi f_c t$, where $f_m < B$ The average side-band power for the AM signal given above is:

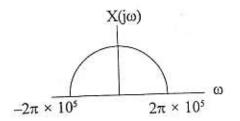
(A) 25 W

26

2

- (B) 12.5 W
- (C) 6.25 W
- (D) 3.125 W
- 52. Which block is not present in Superheterodyne receiver?
 - (A) IF Amplifier and Filter
 - (B) RF Amplifier and Filter
 - (C) Mixer
 - (D) Schmitt Trigger
- 53. The IF is 455 kHz. If the radio receiver is tuned to 855 kHz, the local oscillator frequency is:
 - (A) 455 kHz
 - (B) 1310 kHz
 - (C) 1500 kHz
 - (D) 1520 kHz
- 54. A 10 MHz carrier is frequency modulated by a sinusoidal signal of 500 Hz, the maximum frequency deviation being 50 KHz. The bandwidth required as given by the Carson's rule is:
 - (A) 205 kHz
 - (B) 300 kHz
 - (C) 305 kHz
 - (D) 101 kHz
- In TV transmission, sound signal is ______ modulated.
 - (A) Amplitude
 - (B) Frequency
 - (C) Phase
 - (D) None of the above

- A carrier A_c.cos(ω_ct) is frequency modulated by a singla E_m.cos(ω_mt). The modulation index is m_f. The expression for the resulting FM signal is:
 - (A) $A_c \cdot \cos[\omega_c t + m_f \cdot \sin(\omega_m t)]$
 - (B) $A_c.cos[\omega_c t + m_f cos(\omega_m t)]$
 - (C) $A_c.\cos[\omega_c t + 2\pi.m_f \sin(\omega_m t)]$
 - (D) $A_c \cdot \cos[\omega_c t + 2\pi \cdot m_r E_m \cdot \omega_m \cdot \cos(\omega_m t)]$
- Figure given below shows Fourier spectra of signal x(t):



The Nyquist sampling rate for x(t) is:

- (A) 100 kHz
- (B) 200 kHz
- (C) 300 kHz
- (D) 50 kHz
- 58. The PAM signal can be detected by:
 - (A) Bandpass filter
 - (B) Bandstop filter
 - (C) Highpass filter
 - (D) Lowpass filter
- 59. The main disadvantage of PCM is:
 - (A) Large bandwidth
 - (B) Large power
 - (C) Complex circuitry
 - (D) Quantization noise
- In PWM signal reception, the Schmitt trigger circuit is used:
 - (A) To remove noise
 - (B) To produce ramp signal
 - (C) For synchronization
 - (D) None of the above

- The five flags in 8085 are designated as: 1.
 - (A) Z, CY, S, P, AC
 - (B) D, Z, S, P, AC
 - (C) Z, C, S, P, AC
 - (D) D, CY, S, P, AC
- In 8085, pins for SID and SOD are:
 - (A) 4 and 5 respectively
 - (B) 5 and 4 respectively
 - (C) 3 and 4 respectively
 - (D) 4 and 3 respectively
- In 8085 microprocessor:
 - (A) P flag is set when the result has even parity
 - (B) P flag is set when the result has odd parity
 - (C) P flag is reset when the result has even parity
 - (D) None of the above
- In 8085 microprocessor, HL register pair is used for storing:
 - (A) Address of memory
 - (B) Data
 - (C) Address of next instruction
 - (D) Address of current instruction
- What is the vectored address of interrupt RST5?
 - (A) 0040 H
 - (B) 0028 H
 - (C) 0005 H
 - (D) · 0008 H

- 6. P: Program counter is the register, which stores the address of the next instruction to be executed.
 - Q: Stack pointer stores the address of the top of the stack.

Out of these two statements, which statement(s) is (are) true?

- (A) Only P
- (B) Only Q
- (C) Both P and Q
- (D) None of them
- A stack is: 7.
 - (A) An 8-bit register in the 8085 microprocessor
 - (B) A 16-bit register in the 8085 microprocessor
 - (C) A set of memory locations in R/W memory reserved for storing information temporarily during the execution of a program
 - (D) A 16-bit memory address stored in the program counter

8. Consider the table given below

IO/M	S ₁	S	Machine cycle
0	1	1	X
1	0	1	Y
1	1	1	Z

Here S_0 and S_1 are status signals.

- X, Y, Z are respectively:
- (A) Interrupt Acknowledgment, I/O read, Opcode Fetch
- (B) Interrupt Acknowledgment, I/O write,
 Opcode Fetch
- (C) Opcode Fetch, I/O read, Interrupt Acknowledgment
- (D) Opcode Fetch, I/O write, Interrupt Acknowledgment
- 9. At 100 % amplitude modulation, the power in each sideband is ______ of that of carrier.
 - (A) 50 %
 - (B) 40 %
 - (C) 60 %
 - (D) 25 %
- 10. Consider the amplitude modulated (AM) signal $A_c \cos \omega_c t + 2\cos \omega_m t \cos \omega_c t$. For demodulating the signal using envelope detector, the minimum value of A_C should be :
 - (A) 2
 - (B) 1
 - (C) 0.5
 - (D) 0

- 11. In amplitude modulation, bandwidth is _____ the highest frequency of audio signal.
 - (A) Thrice
 - (B) Four times
 - (C) Twice
 - (D) None of the above
 - 12. Superheterodyne principle refers to:
 - (A) Using a large number of amplifier stages
 - (B) Using a push-pull circuit
 - (C) Obtaining lower fixed intermediate frequency
 - (D) Obtaining higher fixed intermediate frequency
 - 13. The signal $\cos\omega_{c}t + 0.5\cos\omega_{m}t.\sin\omega_{c}t$ is :
 - (A) FM only
 - (B) AM only
 - (C) Both AM and FM
 - (D) Neither AM nor FM
 - 14. Consider the frequency modulated signal $10\cos[2\pi.10^5t + 5\sin(2\pi.1500t) + 7.5\sin(2\pi.1000t)]$ with carrier frequency of 10^5 Hz. The modulation index is:
 - (A) 12.5
 - (B) 10
 - (C) 7.5
 - (D) 5

- The modulation frequency of an FM is doubled. 19. Pulse Time Modulation (PTM) includes: 15. How does the modulation index change?
 - (A) Gets halved
 - (B) Gets doubled
 - (C) Gets increased by 50 percent
 - (D) Remains unchanged
- The major advantage of FM over AM is:
 - (A) Reception is less noisy
 - (B) Higher carrier frequency
 - (C) Smaller bandwidth
 - (D) Small frequency deviation
- A signal of maximum frequency of 10 kHz is sampled at Nyquist rate. The time interval between two successive samples is:
 - (A) 50 µs
 - (B) 100 μs
 - (C) 1000 us
 - (D) 5 µs
- 18. Drawback of using PAM method is:
 - (A) Bandwidth is very large as compared to modulating signal
 - (B) Varying amplitude of carrier varies the peak power required for transmission
 - (C) Due to varying amplitude of carrier, it is difficult to remove noise at receiver
 - (D) All of the above

- - (A) Pulse width modulation
 - (B) Pulse position modulation
 - (C) Pulse amplitude modulation
 - (D) Both (A) and (B)
- 20. In Pulse Code Modulation System:
 - (A) Quantising noise can be overcome by companding
 - (B) Large bandwidth is required
 - (C) Quantising noise can be reduced by decreasing the number of standard levels
 - (D) Suffers from the disadvantage of its incompatibility with Time Division Multiplexing (TDM)
- Thevenin's theorem replaces a complicated circuit facing a load by an:
 - (A) Ideal voltage source and parallel resistor
 - (B) Ideal current source and parallel resistor
 - (C) Ideal current source and series resistor
 - (D) Ideal voltage source and series resistor
- The output voltage of an ideal voltage source is:
 - (A) Zero
 - (B) Constant
 - (C) Dependent on load resistance
 - (D) Dependent on internal resistance

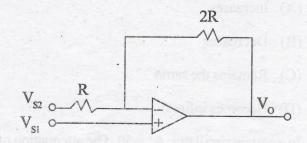
23.	The total reactance of a series RLC circuit at 27.	Zener diodes are used primarily as:
	resonance is:	(A) Amplifiers
	(A) Zero	(B) Voltage regulators
	(B) Equal to the resistance	(C) Rectifiers
	(C) Infinity	(D) Oscillators
	(D) Capacitive	ci ic accided valtage
24.	If the value of resonant frequency is 50 kHz in a 28.	
	series RLC circuit along with the bandwidth of	with a peak value of 200V is:
	about 1 kHz, then what would be the value of	(A) 63.7 V
	quality factor?	(B) 127.3 V
	(A) 50	(C) 141 V
	(B) 5 (C) 100	(D) 0 V
	(D) 500 29	. In a transistor if $\beta = 100$ and collector current is
0.5	(D) 300	10 mA, then emitter current I _E is:
25.	coefficient of resistance.	
		(A) 100 mA
	(A) Positive	(B) 10.1 mA
	(B) Zero	(C) 110 mA
	(C) Negative	(D) None of the above
	(D) None of the above	Call Call in it not on NIDN
26.	The leakage current across a pn junction is due 30	
	to:	transistor?
	(A) Minority carriers	(A) BC548
	(B) Majority carriers	(B) BC557B
	(C) Junction capacitance	(C) 2N2222
	(D) None of the above	(D) BC547B

- 31. In voltage divider bias, $V_{CC} = 25 \text{ V}$; $R_1 = 10 \text{ k}\Omega$ 35. The octal equivalent of (B2F)₁₆ is: (Upper resistor in the divider); $R_1 = 2.2 \text{ k}\Omega$ (Lower resistor in the divider); $R_c = 3.6 \text{ k}\Omega$ and $R_{\rm E} = 1 k \Omega$. Assuming Silicon transistor, what is the emitter voltage?
 - (A) 6.7 V
 - (B) 5.3 V
 - (C) 4.9 V
 - (D) 3.8 V
- 32. In a JFET, I_{DSS} is known as:
 - (A) Drain to source current with source open
 - (B) Drain to source current with gate shorted to ground
 - (C) Drain to source current with gate open
 - (D) Drain to source current with source shorted to ground
- The logic function $f = (x.\overline{y}) + (\overline{x}.y)$ is the same
 - (A) $f = (x + y)(\overline{x} + \overline{y})$
 - (B) $f = (\overline{x} + y)(x + \overline{y})$
 - (C) $f = (x.y). (\overline{x} \overline{y})$
 - (D) None of the above
- 34. How many data select lines are required for selecting eight inputs?
 - (A) 1
 - (B) 2
 - (C) 3
 - (D) 4

- - (A) (5547)₈ *
 - (B) (5457)₈
 - (C) (7547)₈
 - (D) (11010)₈
- 36. While assigning the bit(s) to the cells, Karnaugh Map follows:
 - (A) Excess-3 codes
 - (B) Gray code
 - (C) Straight binary code
 - (D) BCD code
- 37. A square wave with a period of 10 µs drives a T flip-flop (with T at high level). The period of the output signal will be:
 - (A) 100 us
 - (B) 20 μs
 - (C) 10 µs
 - (D) 5 µs
- 38. How many flip-flops are required to produce a divide-by-128 device?
 - (A) 1
 - (B) 4
 - (C) 6
 - (D) 7
- In this type of counter, the output of the last stage is connected to the D input of the first stage:
 - (A) Ring Counter
 - (B) Johnson Counter
 - (C) Up-Down Counter
 - (D) All of the above

40.	There ar	e basic types of shift registers.	45.	Whe	n negative voltage feedback is applied to an	
	(A) Six	(A) E-pun DIP IC		ampl	lifier, its bandwidth:	
	(B) Fo	ur (8)		(A)	Increases	
	(C) On	ne omittament at the		(B)	Decreases	
	(D) Ma	any Dissertant and State of the Control of the Cont		` '	Remains the same	
41.	-	_ coupling has the best frequency				
	respons	e.		(D)	Becomes infinite	
	(A) RO	· momenta (A)	46.	Inac	certain oscillator, $A_v = 50$. The attenuation of	
	(B) Tra	ansformer		the f	eedback circuit must be:	
	(C) Di	rect		(A)	1	
	(D) No	one of the above			0.01	
42.	In an RO	C coupling scheme, the coupling capacitor				
		C _c must be large enough:		(C)	10	
		pass d.c. between the stages		(D)	0.02	
	(B) No	ot to attenuate the low frequencies	47.	The	resonant angular frequency of an RC	
	(C) No	C) Not to attenuate the high frequencies		oscillator is:		
	(D) To	o dissipate high power			1	
43.		power amplifier has the highest		(A)	$\frac{1}{RC}$	
	collecto	or efficiency.		(D)	1	
	(A) C			(B)	$2\pi RC$	
	(B) A	4400 ha		(C)	1	
	(C) B			(0)	2π√LC	
	(D) A			(D)	1 (math) opelet. (d)	
44.		ansistor amplifier feeds a load of low		(-)	2πLC	
	resistance (e.g. speaker), then voltage gain will be:		48.		is a fixed frequency oscillator.	
				(A)	Phase-shift oscillator	
	(A) H			(B)	Hartley oscillator	
		ery high				
	(C) M	foderate		(C)	Colpitt's oscillator	
	(D) L	ow		(D)	Crystal oscillator	

49. In the op-amp circuit shown below, the voltage V_o is:



- (A) $3V_{s1} 6V_{s2}$
- (B) $2V_{s1} 3V_{s2}$
- (C) $2V_{s1} 2V_{S2}$
- (D) $3V_{s1} 2V_{S2}$
- 50. CMRR for an OP-AMP is:
 - (A) $20 \log_{10} \left(\frac{A_{com}}{A_{diff}} \right)$
 - (B) $20 \log_{10} \left(\frac{A_{diff}}{A_{com}} \right)$
 - (C) $20 \log_{20} \left(\frac{A_{com}}{A_{diff}} \right)$
 - (D) $10\log_{10}\left(\frac{A_{diff}}{A_{com}}\right)$
- 51. Op-amp integrator uses:
 - (A) Capacitor as feedback element
 - (B) Resistor as feedback element
 - (C) Inductor as feedback element
 - (D) A simple wire as feedback element

- 52. 555 timer is a :
 - (A) 8-pin DIP IC
 - (B) 8-pin TOP IC
 - (C) 14-pin DIP IC
 - (D) 8-pin flat package IC
- 53. A galvanometer in series with a high resistance is called:
 - (A) An ammeter
 - (B) A voltmeter
 - (C) A wattmeter
 - (D) Ohmmeter
- 54. Two multimeters A and B have sensitivities of $10 \text{ k}\Omega/\text{V}$ and $30 \text{ k}\Omega/\text{V}$ respectively. Then :
 - (A) Multimeter A is more sensitive
 - (B) Multimeter B is more sensitive
 - (C) Both are equally sensitive
 - (D) None of the above
- 55. The value of multiplier resistor required to design a voltmeter of 10V range with a PMMC of internal resistance of 1 K Ω and $I_{fsd} = 100 \ \mu A$ is :
 - (A) 1 KΩ
 - (B) 9 KΩ
 - (C) 10 KΩ
 - (D) 99 KΩ
- 56. The value of external resistance at half scale deflection in case of series type ohmmeter is equal to:
 - (A) Half the internal resistance of the meter
 - (B) The internal resistance of the meter
 - (C) ½th of the internal resistance of the meter
 - (D) None of the above

- 57. Schering bridge is used to:
 - (A) Measure the insulating properties of electrical cables and equipment
 - (B) Determine the inductance
 - (C) Measure mutual inductance
 - (D) Measure low resistance
- 58. AQUADAG is a:
 - (A) Non-conductive coating on the screen of a CRT to collect the high velocity electrons
 - (B) Non-conductive coating on the screen of a CRT to collect the secondary-emission electrons
 - (C) Conductive coating on the screen of a CRT to collect the secondary-emission electrons
 - (D) None of these

- 59. The colour of the spot on the screen of a CRO is a characteristic of:
 - (A) Electron gun in a CRT
 - (B) The type of the waveform being observed
 - (C) The coating material on the screen
 - (D) The velocity of the electrons striking the screen
- 60. Self generating type transducers are ______transducers.
 - (A) Active
 - (B) Passive
 - (C) Secondary
 - (D) Inverse

Deli-mo

Sr. No. 220

ENTRANCE TEST-2017

SCHOOL OF APPLIED SCIENCES & TECHNOLOGY ELECTRONICS

Total	Questions	
HUBRARI		

60

Time Allowed

70 Minutes

Question	Booklet	Series
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B

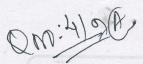
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A RUAN A				1000	

Instructions for Candidates:

- 1. Write your Roll Number in the space provided at the top of this page of Question Booklet and fill up the necessary information in the spaces provided on the OMR Answer Sheet.
- 2. OMR Answer Sheet has an Original Copy and a Candidate's Copy glued beneath it at the top. While making entries in the Original Copy, candidate should ensure that the two copies are aligned properly so that the entries made in the Original Copy against each item are exactly copied in the Candidate's Copy.
- 3. All entries in the OMR Answer Sheet, including answers to questions, are to be recorded in the Original Copy only.
- 4. Choose the correct / most appropriate response for each question among the options A, B, C and D and darken the circle of the appropriate response completely. The incomplete darkened circle is not correctly read by the OMR Scanner and no complaint to this effect shall be entertained.
- 5. Use only blue/black ball point pen to darken the circle of correct/most appropriate response. In no case gel/ink pen or pencil should be used.
- 6. Do not darken more than one circle of options for any question. A question with more than one darkened response shall be considered wrong.
- 7. There will be 'Negative Marking' for wrong answers. Each wrong answer will lead to the deduction of 0.25 marks from the total score of the candidate.
- 8. Only those candidates who would obtain positive score in Entrance Test Examination shall be eligible for admission.
- 9. Do not make any stray mark on the OMR sheet.
- 10. Calculators and mobiles shall not be permitted inside the examination hall.
- 11. Rough work, if any, should be done on the blank sheets provided with the question booklet.
- 12. OMR Answer sheet must be handled carefully and it should not be folded or mutilated in which case it will not be evaluated.
- 13. Ensure that your OMR Answer Sheet has been signed by the Invigilator and the candidate himself/herself.
- 14. At the end of the examination, hand over the OMR Answer Sheet to the invigilator who will first tear off the original OMR sheet in presence of the Candidate and hand over the Candidate's Copy to the candidate.

1

[Turn over



An 8085 assembly language program is given below. Assume that the carry flag is initially unset. The content of the accumulator after the execution of the program

MVIA, 07H

RLC

MOV B,A

RLC

RLC

ADD B

RRC

- (A) 8CH
- (B) 64H
- 23H (C)
- (D) 15H
- For 8085 microprocessor, the following program is executed

MVIA, 05H;

MVIB, 05H;

PTR: ADD B;

DCR B;

JNZ PTR;

ADI 03H;

HLT;

At the end of program, accumulator contains

- (A) 17 H
- 20 H (B)
- 23 H (C)
- (D) 05 H
- 3. For the 8085 assembly language program given below, the content of the accumulator after the execution of the program is

3000 MVIA, 45H

3002 MOV B, A

3003 STC

3004 CMC

3005 RAR

3006 XRAB

00H (A)

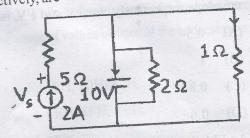
- 45H (B)
- 67H (C)
- (D) E7H

- An 8085 microprocessor executes "STA 1234H" with starting address location 1FFEH (STA copies the contents of the accumulator to the 16 bit address location). While the instruction is fetched and executed, the sequence of values written at the address pins A15-A8 is:
 - (A) 1FH, 1FH, 20H, 12H
 - (B) 1FH, FEH, 1FH, FFH
 - 1FH, 1FH, 12H, 12H (C)
 - (D) 1FH, 1FH, 12H, 20H
- If the carrier of a 100% modulated AM wave it suppressed, the percentage power saving will be
 - 50 (A)
 - (B) 150
 - (C) 100
 - 66.66 (D)
- Consider the signal $s(s)=m(t)\cos 2\pi f c t + m^{\prime}(t) \sin 2\pi f c t$ where m[^] (t) denotes the Hilbert transform of m(t) and the bandwidth of m(t) is very small compared to fc. The signal s(t) is a
 - high-pass signal (A)
 - (B) low-pass signal
 - (C) band-pass signal
 - double sideband suppressed carrier signal
 - A message signal $m(t) = \cos 200pt + 4cospt$ modulates the carrier $c(t) = \cos 2p f_c t$ where $f_c = 1$ MHz to produce an AM signal. For demodulating the generated AM signal using an envelope detector, the time constant RC of the detector circuit should satisfy
 - (A) 0.5 ms < RC < 1 ms
 - $1 \mu s << RC < 0.5 ms$ (B)
 - RC << 1 µs (C)
 - (D) RC >> 0.5 ms

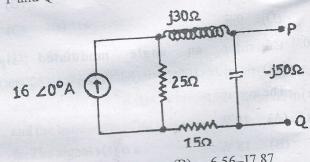
8.	Consider sinusoidal modulation in an AM system.	13.	One of the disadvantages of PCM is
	Assuming no over modulation, the modulation index $(\boldsymbol{\mu})$		(A) It requires large bandwidth
	when the maximum and minimum values of the		(B) Very high noise
	envelope respectively, are 3 V and 1 V, is		(C) Cannot be decoded easily
	(A) 0.5		(D) All of the above
	(B) 1	14.	An analog signal is band-limited to 4 kHz, sampled a
	(C) 0.8		the Nyquist rate and the samples are quantized into
	(D) 0.6		4 levels. The quantized levels are assumed to be
9.	An FM signal with a modulation index m _f is passed		independent and equally probable. If we transmit two
	through a frequency Tripler. The wave in the output		quantized samples per second, the information rate is bits / second.
	of the Tripler will have a modulation index of		(D) (A) is false (R) is true.
	(A) $m_f/3$ (B) $3m$		Consider the following statements resorted as
	Common Gata for Questions 16 to 27 Q fine 9		(B) 2 (Danoisonal Davidiense
	(C) m _f		(C) 3 (assistant approximately 4.7)
9	(D) 9m _f		(D) 4 Designation of the large
10.	Consider an angle modulated signal	15.	A band-limited signal with a maximum frequency o
	$x(t)=6\cos[2\pi x 106t+2\sin(8000\pi t)+4\cos(8000pt)] V.$ The average power of $x(t)$ is		5 kHz is to be sampled. According to the sampling theorem, the sampling frequency which is not valid is
	(A) 10 W		CHIEF CAME AND THE CAME AND
	(B) 18 W		5 hro. 1 671V 404
	(C) 20 W (D) 28 W		(B) 12 kHz
			(C) 15 kHz
11.	An FM radio receiver which is tuned to a 91.6 MHz		(D) 20 kHz
11.	broadcast station may receive an image frequency of	16.	Which one of the following is used to generate PWM
	(A) 102.3 MHz	Surg	(A) Free running multivibrator
	(B) 113 MHz		(B) Mono-stable multivibrator
	(C) 70.2 MHz		(C) JK flip flop
	(D) 80.9 MHz		(D) Schmitt trigger
12.	Commercial frequency deviation of FM is	17.	Generation of FM signal from PM signal requires
14.	200		(A) Differentiator
			(B) Integrator
	(B) 75 kHz	viite	(C) Band pass filter
	(C) 80 kHz		(D) Oscillator
	(D) 65 kHz		attams its minimum value.
DA.	J-11108–B	3	[Turn over

- Assertion (A): Thermistors are commonly used to measure hot spot temperatures in electric machines.
 - Thermistor has the advantages of high Reason (R): temperature coefficient, small size and high speed of response.
 - Both (A) and (R) are true and (R) is correct (A) explanation of (A)
 - (B) Both (A) and (R) are true but (R) is not correct explanation of (A)
 - (A) is true (R) is false (C)
 - (A) is false (R) is true
 - Consider the following statements regarding phase sensitive detector -
 - The detector reads zero when phases of input signal and reference signal are different
 - The detector acts as a linear rectifier 2.
 - The detector can be used as vector voltmeter 3. Of the above statements which are correct?
 - 1, 2, 3 (A)
- 1 and 2 (B)
- 2 and 3
- 1 and 3 (D)
- Companding is used 20.
 - to overcome quantizing noise in PCM (A)
 - in PCM transmitters, to allow amplitude limited (B) in the receivers
 - to protect small signals in PCM from quantizing (C) distortion
 - (D) in PCM receivers, to overcome impulse noise.
 - For parallel RLC circuit, which one of the following statements is NOT correct?
 - The bandwidth of the circuit decreases if R is (A) increased
 - The bandwidth of the circuit remains same if L (B) is increased
 - At resonance, input impedance is a real quantity (C)
 - At resonance, the magnitude of input impedance (D) attains its minimum value.

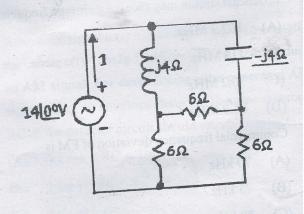
The current Is in Amps in the voltage source, and voltage V_s in Volts across the current source respectively, are



- 13, -20(A)
- 8, -10(B)
- -8,20(C)
- -13,20(D)
- In the circuit shown below, the Norton equivalent current in amperes with respect to the terminals P and Q is



- 6.4 j4.8
- 6.56-J7.87 (B)
- 10+j0
- 16 + j0(D)
- 24. In the circuit shown below, the current I is equal to



- 14A
- 2.0 A (B)
- 2.8 A (C)
- 3.2 A (D)

25. Consider the following statement:

If an electric field is applied to an n type semiconductor bar, the electrons and holes move in opposite directions due to their opposite charges. The net current is -

- both due to electrons and holes with electrons as majority carriers
- 2. sum of hole and electron currents
- 3. difference between electron and hole currents.

Which of above statements are correct?

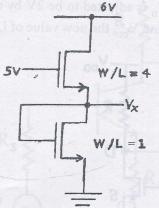
- (A) 1 only
- (B) 1 and 2
- (C) 2 only
- (D) 3 only

Common data for Questions 26 to 28

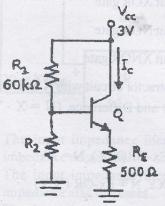
At room temperature a Si p-n junction diode with n-side is doped with donor concentration of 10^{16} cm⁻³ and p-side is doped with acceptor concentration of 10^{17} cm⁻³. The relative permittivity of Si, Er = 11.7, $n_i = 10^{10}$ cm⁻³.

- 26. The built in potential is
 - (A) 360 mV
 - (B) 420 mV
 - (C) 640 mV
 - (D) 780 mV
- 27. The depletion region width is
 - (A) 3.37 μm
 - (B) 33.7 μm
 - (C) 5.28 μm
 - (D) 8.91 μm
- 28. The junction capacitance per unit area with zero bias is
 - (A) $3.02 \,\mu\text{F/m}^2$
 - (B) 26.15 μF/m²
 - (C) $51.92 \mu F/m^2$
 - (D) 72.75 μF/m²

29. In the circuit shown below, for the MOS transistors, $u_n C_{ox} = 100 \ \mu A/V^2$ and the threshold voltage $V_t = 1V$. The voltage V_x at the source of the upper transistor is :

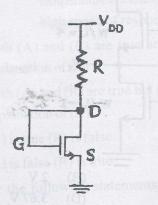


- (A) 1 V
- (B) 2 V
- (C) 3 V
- (D) 3.67 V
- 30. For a BJT the common base current gain $\alpha=0.98$ and the collector base junction reverse bias saturation current $I_{CO}=0.6\mu A$. This BJT is connected in the common emitter mode and operated in the active region with a base drive current $I_B=20\mu A$. The collector current IC for this mode of operation is
 - (A) 0.98 mA
- (B) 0.99 mA
- (C) 1.0 mA
- (D) 1.01 mA
- 31. In the circuit shown below, the silicon npn transistor Q has a very high value of β . The required value of R_2 in $k\Omega$ to produce $I_C = 1$ mA is



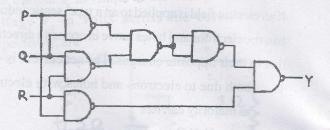
- (A) 20
- (B) 30
- (C) 40
- (D) 50

32. For the n-channel MOS transistor shown in the figure, the threshold voltage V_{Th} is 0.8 V. Neglect channel length modulation effects. When the drain voltage $V_{D} = 1.6$ V, the drain current I_{D} was found to be 0.5 mA. If V_{D} is adjusted to be 2V by changing the values of R and V_{DD} , the new value of I_{D} (in mA) is

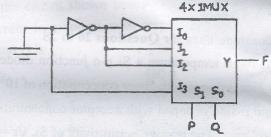


- (A) 0.625
- (B) 0.75
- (C) 1.125
- (D) 1.5
- 33. A 3-input majority gate is defined by the logic function M(a,b,c)=ab+bc+ca. Which one of the following gates is represented by the function $M(\overline{M(a,b,c)},M(a,b,\overline{c}),c)$?
 - (A) 3-input NAND gate
 - (B) 3-input XOR gate
 - (C) 3-input NOR gate
 - (D) 3-input XNOR gate
- 34. In a half-subtractor circuit with X and Y as inputs, the Borrow (M) and Difference, (N = X Y) are given by
 - (A) M = Ex-OR(X,Y), N = XY
 - (B) M = XY, N = Ex-OR(X,Y)
 - (C) M = X'Y, N = Ex-OR(X,Y)
 - (D) M = XY, N = (Ex-OR(X,Y))

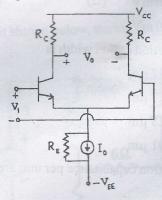
35. The output Y in the circuit below is always '1' when



- (A) two or more of the inputs P,Q,R are '0'
- (B) two or more of the inputs P,Q,R are '1'
- (C) any odd number of the inputs P,Q,R is '0'
- (D) any odd number of the inputs P,Q,R is '1'
- 36. The logic function implemented by the circuit below is (ground implies logic 0)

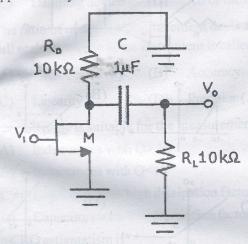


- (A) F = PANDQ
- (B) F = P OR Q
- (C) F=P XNOR Q
- (D) F = P XOR Q
- 37. In the differential amplifier shown in the figure, the magnitudes of the common-mode and differential-mode gains are A_{cm} and A_d, respectively. If the resistance R_e is increased, then



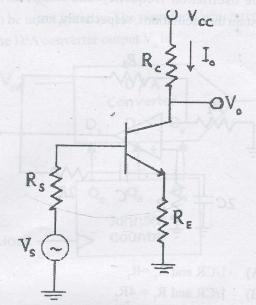
- (A) A_{cm} increases
- (B) common-mode rejection ratio increases
- (C) A_d increases
- (D) common-mode rejection ratio decreases

38. The ac schematic of an NMOS common-source stage is shown in the figure below, where part of the biasing circuits has been omitted for simplicity. For the n channel MOSFET M, the Transconductance $g_m = 1 \text{mA/V}$, and body effect and channel length modulation effect are to be neglected. The lower cutoff frequency in Hz of the circuit is approximately at

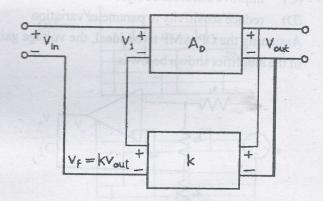


- (A) 8
- (B) 32
- (C) 50
- (D) 200
- 39. An RC coupled amplifier is assumed to have a single pole low frequency transfer function. The maximum lower cut-off frequency allowed for the amplifier to pass 50 Hz square wave with no more than 10% tilt is:
 - (A) 150 Hz
 - (B) 100 Hz
 - (C) 200 Hz
 - (D) 120 Hz
- 40. The cascode amplifier is a multistage configuration of
 - (A) CC-CB
 - (B) CE-CB
 - (C) CB-CC
 - (D) CE-CC

41. The feedback topology in the amplifier circuit the base bias circuit is not shown for (simplicity) in the figure is

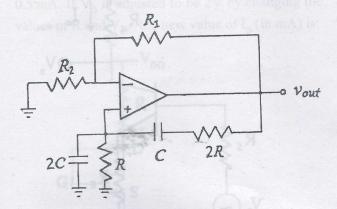


- (A) Voltage shunt feedback
- (B) Current series feedback
- (C) Current shunt feedback
- (D) Voltage series feedback
- 42. In a voltage-voltage feedback as shown below, which one of the following statements is TRUE if the gain k is increased?

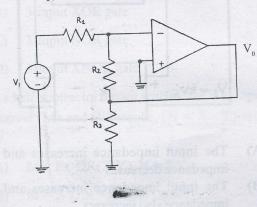


- (A) The input impedance increases and output impedance decreases
- (B) The input impedance increases and output impedance also increases
- (C) The input impedance decreases and output impedance also decreases
- (D) The input impedance decreases and output impedance increases

The circuit shown in the figure has an ideal op-amp. The oscillation frequency and the condition to sustain the oscillations, respectively, are

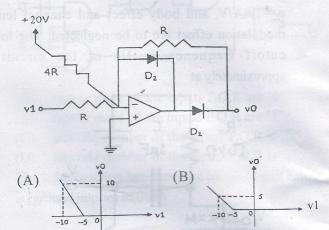


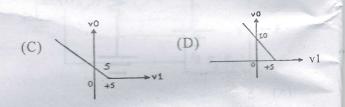
- 1/CR and $R_1 = R_2$ (A)
- 1/CR and $R_1 = 4R_2$ (B)
- 1/2CR and $R_1 = R_2$ (C)
- 1/2CR and $R_1 = 4R_2$ (D)
- Negative feedback in a closed-loop control system 44. DOES NOT
 - reduce the overall gain (A)
 - reduce bandwidth (B)
 - improve disturbance rejection (C)
 - reduce sensitivity to parameter variation
- Assuming the OP-AMP to be ideal, the voltage gain 45. of the amplifier shown below is



- -(R, ||R,)/R
- $-(R_2+R_3)/R_1$

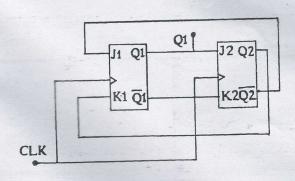
The transfer characteristic for the precision rectifier 46. circuit shown below is (assume ideal OP-AMP and practical diodes)





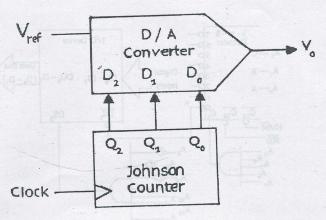
- An amplifier using an op-amp with a slew rate 47. SR=1 V/µsec has a gain of 40dB. If this amplifier has to faithfully amplify sinusoidal signals from dc to 20 kHz without any slew rate distortion, then the input signal must not exceed
 - (A) 795 mV
- 395 mV
- (C) 79.5 mV (D) 39.5 mV
- The ideal op-amp has the following characteristics 48.
 - $Ri=\infty$, $Av=\infty$, Ro=0(A)
 - Ri=0, Av=∞, Ro=0 (B)
 - $Ri=\infty$, $Av=\infty$, $Ro=\infty$ (C)
 - $Ri=0, Av=\infty, Ro=\infty$
- The function of shunt in an ammeter is to 49.
 - bypass the current
 - increase the sensitivity of the ammeter (B)
 - increase the resistance of ammeter (C)
 - none of the above (D)

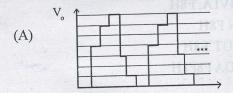
- 50. In majority of instruments damping is provided by
 - (A) fluid friction
- (B) spring
- (C) eddy currents
- (D) all of the above
- 51. Which of the following essential features is possessed by an indicating instrument?
 - (A) Deflecting device
- B) Controlling device
- (C) Damping device
- (D) All of the above
- 52. The ratio of maximum displacement deviation to the full scale deviation of the instrument is called:
 - (A) Static sensitivity (B)
- (B) Accuracy
 - (C) Linearity
- (D) Precision
- 53. Hay's Bridge is suitable for the measurement of
 - (A) Inductances with Q> 10
 - (B) Inductances with Q<10
 - (C) Capacitors with high dissipation factor
 - (D) Capacitors with low dissipation factor
- 54. In CRO astigmatism is:
 - (A) Source of generating fast electrons
 - (B) Media for absorbing secondary emission electrons
 - (C) An additional focus control
 - (D) Time delay control in the vertical deflection system
- 55. The outputs of the two flip-flops Ql, Q2 in the figure shown are initialized to 0,0. The sequence generated at Ql upon application of clock signal is:

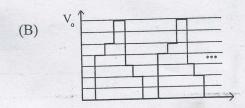


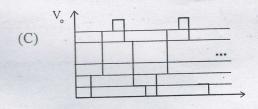
- (A) 01110...
- (B) 01010...
- (C) 00110...
- (D) 01100...

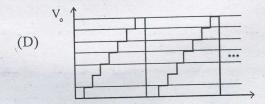
56. The output of a 3-stage Johnson (twisted ring) counter is fed to a digital-to analog (D/A) converter as shown in the figure below. Assume all the states of the counter to be unset initially. The waveform which represents the D/A converter output V_{\circ} is



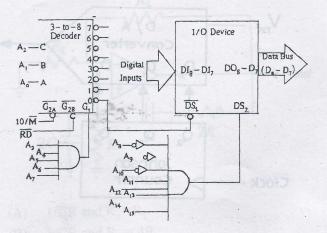








57. For the 8085 microprocessor, the interfacing circuit to input 8-bit digital data (DI0 - DI7) from an external device is shown in the figure. The instruction for correct data transfer is



- (A) MVIA, F8H
- (B) IN F8H
- (C) OUT F8H
- (D) LDA F8F8H

- 58. In an 8085 microprocessor, the shift registers which store the result of an addition and the overflow bit are, respectively
 - (A) B and F
 - (B) A and F
 - (C) H and F
 - (D) A and C
- 59. Which one of the following is not a vectored interrupt?
 - (A) TRAP
 - (B) INTR
 - (C) RST 7.5
 - (D) RST 3
- 60. The register in the 8085A that is used to keep track of the memory address of the next op-code to be run in the program is the:
 - (A) stack pointer
 - (B) program counter
 - (C) instruction pointer
 - (D) Accumulator

		105
C.	No	100
SI.	110.	100

ENTRANCE TEST-2016

FACULTY OF APPLIED SCIENCE & TECHNOLOGY

M.Sc. ELECTRONICS

Total Questions	:	60	Question Booklet Ser	
Time Allowed	•	70 Minutes	Roll No.:	nol4 £

Instructions for Candidates:

- 1. Write your Roll Number in the space provided at the top of this page of Question Booklet and fill up the necessary information in the spaces provided on the OMR Answer Sheet.
- 2. OMR Answer Sheet has an Original Copy and a Candidate's Copy glued beneath it at the top. While making entries in the Original Copy, candidate should ensure that the two copies are aligned properly so that the entries made in the Original Copy against each item are exactly copied in the Candidate's Copy.
- 3. All entries in the OMR Answer Sheet, including answers to questions, are to be recorded in the Original Copy only.
- 4. Choose the correct / most appropriate response for each question among the options A, B, C and D and darken the circle of the appropriate response completely. The incomplete darkened circle is not correctly read by the OMR Scanner and no complaint to this effect shall be entertained.
- 5. Use only blue/black ball point pen to darken the circle of correct/most appropriate response. In no case gel/ink pen or pencil should be used.
- 6. Do not darken more than one circle of options for any question. A question with more than one darkened response shall be considered wrong.
- 7. There will be 'Negative Marking' for wrong answers. Each wrong answer will lead to the deduction of 0.25 marks from the total score of the candidate.
- 8. Only those candidates who would obtain positive score in Entrance Test Examination shall be eligible for admission.
- 9. Do not make any stray mark on the OMR sheet.
- 10. Calculators and mobiles shall not be permitted inside the examination hall.
- 11. Rough work, if any, should be done on the blank sheets provided with the question booklet.
- 12. OMR Answer sheet must be handled carefully and it should not be folded or mutilated in which case it will not be evaluated.
- 13. Ensure that your OMR Answer Sheet has been signed by the Invigilator and the candidate himself/herself.
- 14. At the end of the examination, hand over the OMR Answer Sheet to the invigilator who will first tear off the original OMR sheet in presence of the Candidate and hand over the Candidate's Copy to the candidate.

CWG-33107-A 1 [Turn over

(D)

- Voltage division law states that the voltage across an impedance in a loop containing 1. a single voltage source and many impedances is given by: The magnitude of impedance only The value of voltage source only (B) The magnitude of impedance and the value of voltage source (C) None of the above
- Norton's theorem can be used to transform a complex network into an equivalent 2. network that contains:
 - A voltage source in parallel with an equivalent resistance (A)
 - A voltage source in series with an equivalent resistance (B)
 - A current source in parallel with an equivalent resistance (C)
 - A current source in series with an equivalent resistance (D)
- A parallel LC resonance circuit has:
 - Maximum impedance at resonance frequency (A)
 - Maximum current at resonance frequency (B)
 - Minimum impedance at resonance frequency (C)
 - None of the above (D)
- 4. Which filter has maximum gain at its center/corner frequency?
 - A lowpass filter (A)

- (B) A highpass filter
- A bandpass filter
- (D) A bandstop filter
- 5. Which of the following shall be created by adding a trivalent impurity to silicon?
 - Germanium (A)

- (B) A p-type semiconductor
- An n-type semiconductor (C)
- (D) A depletion region
- What will be the average value of full-wave rectified voltage with a peak value of 150 V?
 - (A) 127.3 V

(B) 141 V moded on Understident base and shuster) .01

(C) 95.49 V

- (D) 63.5 V
- Which of the following is correct about Zener diode? 7.
 - Positive temperature voltage coefficient (A)
 - Negative temperature voltage coefficient (B)
 - Zero temperature voltage coefficient (C)
 - (D) All of the above

9.	Which o	f the following relat	es between β with α	? (0)		
	(A)	$\beta = \frac{1}{1 - \alpha}$	(B)	$\beta = \frac{1}{1+\alpha}$		
	(C)	$\beta = \frac{\alpha}{1-\alpha}$	(D)	$\beta = \frac{\alpha}{1 + \alpha}$	JPG (
10.	What wi	ll be the collector vo	oltage, if the base emi	tter junction is ope	od the following is an an	
	(A)	Vcc	(B)			
	(C)	Floating	(D)	0.2V		
11.	The inpu	at resistance of a con	nmon base (CB) amp	lifier is:		
	(A)	Very low	(B)	Very high		
	(C)	Same as CE	(D)			
12.	Which o	f the following is co	orrect about MOSFE			A) 8)
	(A)	MOSFET has two	modes of operation	: Enhancement and	d Depletion	
	(B)		types: n-channel and			
	(C)	Most of the curren	nt digital ICs are imple	emented using MC	SFETs	
	(D)	All of the above				
13.	Accordi	ng to De-Morgan's	law, $\overline{A} + B$ can be v	vritten as:	4	
	(A)	$A + \overline{B}$	(B)	\overline{A} + \overline{B}		
	(C)	$A.\overline{B}$	(D)	$\overline{A}.\overline{B}$		
						O)
14.	Which o	of the following is th	e correct hexadecima	al representation of	$(103)_{10}$?	
	(A)	7F ₁₆	(B)	67 ₁₆	tensul liw grawoliol oil to r	
	(C)	81 ₁₆	(D)	87 ₁₆		
CV	VC-33107	<i>1</i> _Δ		3	[Turn over	r

8.

Which of the following is used to determine Line regulation?

Changes in load resistance and output voltage

Changes in output voltage and input voltage

Zener current and load current

Load current

(A) (B)

(C)

(D)

CWG-33107-A

(A) $f=1$ (B) $f=(x+y)(x+\bar{y})$ (C) $f=(x,y)+(x\bar{y})$ (D) None of the above 16. Which of the following is the correct octal representation of $(291)_{10}$? (A) 501_4 (B) 443_8 (C) 402_8 (D) 424_8 17. Which among the following logic family has lowest power dissipation? (A) TTL (B) CMOS (C) DTL (D) ECL 18. Which of the following is the correct POS form of the Boolean function $f(A,B,C) = \sum (1,3,5,6)$? (A) $f(A,B,C) = \prod (0,2,7)$ (B) $f(A,B,C) = \prod (0,2,6,7)$ (C) $f(A,B,C) = \prod (0,2,4)$ (D) $f(A,B,C) = \prod (0,2,4,7)$ 19. Which of the following can be performed by a multiplexer? (A) Scrial to Parallel data conversion (B) Parallel to Scrial data conversion (C) Parity Checking (D) None of the above 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μ s drives a T type flip-flop with T=1, what would be the period of the output signal? (A) 6μ (C) 10μ (D) 12μ s 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (C) Inverting R input (C) Inverting R input	15.	Which of	the following is same as the log	ic func	tion $f = xy + x.\overline{y} + \overline{x}.y + \overline{x}.\overline{y}$?		
 (C) f = (x,y)+(x,y) (D) None of the above 16. Which of the following is the correct octal representation of (291)₁₀? (A) 501₈ (B) 443₈ (C) 402₈ (D) 424₈ 17. Which among the following logic family has lowest power dissipation? (A) TIL (B) CMOS (C) DIL (D) ECL 18. Which of the following is the correct POS form of the Boolean function f(A,B,C) = ∑(1,3,5,6)? (A) f(A,B,C) = ∏(0,2,7) (B) f(A,B,C) = ∏(0,2,6,7) 19. Which of the following can be performed by a multiplexer? (A) Serial to Parallel data conversion (B) Parallel to Serial data conversion (C) Parity Checking (D) None of the above 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 µs drives a T type flip-flop with T=1, what would be the period of the output signal? (A) 6µs (B) 24µs (C) 10µs (D) 12µs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (C) Inverting R input 23. Inverting S input (D) Inverting R before tying with S 	10.						
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(A) 501_8 (B) 442_8 (D) 424_8 (D) 424_8 (D) 424_8 (D) 424_8 (E) 442_8 (E)	16	3371.1-16	the following is the correct octal	renrese	entation of (291)?		
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 (A) Serial to Parallel data conversion (B) Parallel to Serial data conversion (C) Parity Checking (D) None of the above 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (B) 24 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input 	19	Which	f the following can be performed	by a mu	altiplexer?	Same	
(B) Parallel to Serial data conversion (C) Parity Checking (D) None of the above 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S	17.		Serial to Parallel data conversio	n			
 (D) None of the above 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (B) 24 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 					owing is correct about MOSFET?		
 20. What is the Excess 3 code for 1011? (A) 1011 (B) 1111 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (B) 24 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 		(C)	Parity Checking				
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 (A) 1011 (C) 1110 (D) 1100 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (B) 24 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 							
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 21. If a square wave clock with a period of 6 μs drives a T type flip-flop with T=l, what would be the period of the output signal? (A) 6 μs (B) 24 μs (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 				, ,			
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would be the period of the output signal? (A) 6 µs (B) 24 µs (C) 10 µs (D) 12 µs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S	1	TC		us drive	es a T type flip-flop with T=1, what		
 (A) 6 μs (B) 24 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 	21.	would k	be the period of the output signal	?	E. (E)		(A)
 (C) 10 μs (D) 12 μs 22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S 				(B)	24 μs		
22. Which of the following will transform an SR type Flip Flop into a D type Flip Flop? (A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S				(D)) 12 μs		
(A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S			dian of (193), 2		owing is the correct hexadecimal rep		
(A) Tying S and R inputs together (B) Inverting S input (C) Inverting R input (D) Inverting R before tying with S	22.	Which	of the following will transform an				
ravo and l			Tying S and R inputs together	(B)) Inverting S input		
				(D) Inverting R before tying with S		
			M45				DOZDE CITY
CWG-35107-A	C	WG-3310			4		

23.	How ma	any Flip Flops are required	to design a M	odulo-14 counter?			
	(A)	14	(B)	3			
	(C)	4 agasto	(D)	5			
24.	How ma	any bits of memory does a I	RAM of 2K >	8 have 2			
27.	(A)	16000	(B)	2024			
	(C)	2008	(D)	16384	0.9		
	(C)	2008	(D)	10364			
25.	What is	the maximum efficiency	y of a class A	A power amplifier	? $\frac{0.0}{50} = \chi$		
	(A)	25%	(B)	50%			
	(C)	79%	(D)	98%			
		notion					
26.	Whicha	mplifier operates in the linea	ar region duri	ng one half cycle?			
	(A)	ClassA	(B)	Class AB			
	(C)	Class B	(D)	Class C			
27.	Which o	f the following is true about	Wien bridge				
	(A)	It has three RC circuits					
	(B)	It has three LC circuits	Ω001			(0)	
	(C)	It has a series RC circuit a	nd a parallel	RC circuit			
	(D)	None of the above					
28.	What she	ould be loop phase shift for	sustained osc	illations?			
	(A)	0° or 360°	(B)	000			
	(C)	180°	(D)	2700	Changing community		
29.	What wi	ll be the gain of a non-inver	ting amplifie	r with $R=3 K\Omega$ and I			
	(A)	4	(B)	5			
	(C)	10	(D)	5.5			
30.	An op-a	mp based Integrator has:					
	(A)	Diode in the feedback pat	h and capacit	ance in the series pat	fthe following can d		
	(B)	Capacitance in the feedba	ck path and r	esistance in the series	s path		
	(C)	Resistance in the feedback	k path and ca	pacitance in the series	s path		
	(D)	Capacitance in the feedba	ick path and c	liode in the series pat	h		
	.c. 22 10=			_	rr.		
CW	G-33107	-A		5_	[Turn	over	

- The 555 timer IC is available as: 31.
 - 8-Pin DIP (A)

(B) 8-Pin TOP

(C) 14-Pin DIP

- (D) 8-Pin Flat Package
- Which of the following describes the frequency of an Astable Multivibrator?
 - (A) $f = \frac{0.9}{(R_1 + 2R_2)C}$ (B) $f = \frac{1.44}{(R_1 + 2R_2)C}$
 - (C) $f = \frac{0.9}{RC}$ (D) $f = \frac{1.44}{RC}$
- 33. In PMMC controlling force is provided by:
 - (A) Eddy Currents

(B) Mechanical Friction

(C) Air

- (D) Spring
- 34. What should be the value of shunt resistance, if a 1mA ammeter with a resistance of 100Ω is to be converted to a 1A ammeter?
 - (A) $0.001\,\Omega$

(B) $0.1001\,\Omega$

 100000Ω (C)

- (D) $100\,\Omega$
- 35. In a series type of ohmmeter, the zero adjustment should be done by:
 - Changing the value of series resistance
 - Changing the value of shunt resistance connected across the meter (B) movement
 - Changing both the series as well shunt resistance (C)
 - Changing the battery voltage (D)
- 36. What is indicated by the high torque to weight ratio in an analog indicating instrument?
 - High friction loss (A)
 - Low friction loss (B)
 - Nothing with regard to friction loss
 - None of the above (D)
- 37. Which of the following can be used to measure the frequency?
 - (A) Maxwell's bridge (B) Schering bridge
 - (C) Heaviside Campbell bridge (D) Wien's bridge

	(A)	Primary electrons				
	(B)	Secondary emission electrons		(ff)		
	(C)	Both primary and secondary em	nission e	lectrons		
	(D)	None of the above		•	(9)	
					hick of the following	
39.	Which o	f the following can act as an inve	rse trans			
	(A)	Electrical resistance potentiome	eter (B)	LVDT		
	(C)	Capacitance Transducer	(D)	Piezo electric crystals		
40.	In wire v	wound strain gauges, the change is	n resista	nce on application of strair	n is mainly due to:	
	(A)	Change in length of wire				
	(B)	Change in diameter of wire		OP operation stack pointer		
	(C)	Change in both length and diam	neter of	wire		
	(D)	Change in resistivity				
				1 POP are 2 Byte instruction		
41.		f the following flags is not includ				
	(A)	Overflow Flag				
	(C)	Sign Flag	(D)	Parity Flag		
	***** 1	of the following externally initiat	ad oper	etions can 8085 Microproc	ressor	
42.	respond		ed open	ations can 6065 whereprov	203301	
	(A)	Reset	(B)	Hold		
	(C)	Both (A) and (B)	(D)	None of the above		
43.	Which o	of the following is not a valid inst	ruction o	of 8085 Microprocessor?		
	(A)	ROR	(B)	MVIA, 35h		
	(C)	STA 2000h	(D)	ADD A, B		
44.	Which	of the following is correct about t				
	(A)	The contents of memory locati	ion spec	ified by 16-bit operand is l	loaded	
		in the accumulator				
	(B)	The contents of memory locat accumulator	tion spe	cified by HL pair is loaded	l in the	
	(C)	Both (A) and (B)				
	(C)					
	(D)	None of the above				
CV	VG-3310'	7 –A		7	[Turn over	

38. An aquadag is used in a CRO to collect: Select behalous and engineering (Messell) TRS (Messell)

45.	How ma	ny RST (Restart) instructions	are includ	ed in the instruction set of 8085	
	Micropr	ocessor?			
	(A)	4	(B)	Secondary emission electrons 2	
	(C)	8	(D)	Hoth primary and secondary cruised 61	
46.	Which o		ne 8085 mi	croprocessor is not automatically	
	(A)	INTR	(B)	TRAP	
	(C)	RSTN	(D)	None of the above	
47.	Which o	f the following is correct abou	t stack ope	ration in 8085 microprocessor?	
	(A)	With every POP operation st			
	(B)	With every POP operation st	ack pointe	er is incremented by 2	
	(C)	Both Push and POP instruction	ons modify	carry flag	
	(D)	Both Push and POP are 2 By	te instruct		
48.	Which o	f the following causes wait stat	tes to be in	troduced in the timing of the 8085	
	micropro	ocessor?			
	(A)	Ready	(B)	Hold	
	(C)	Both Ready and Hold	(D)	None of the above	
49.	The freq	uency components present in s	ingle sided	spectrum of monotone amplitude	
17.		ion with $f_c = 100kHz$ and $f_m =$			
	(A)	100kHz, $1kHz$	(B)	100kHz, 1kHz, 99kHz	
		100kHz, 1kHz, 101kHz	OUA CAUA	100kHz, 101kHz, 99kHz	
		AC.	ICLATIVI ADDA D	ROK (B)	
50.	In ampli			y the peaks of the carrier signal is	(U)
	(A)	Index pobsol at brasson in	(B)	Envelope	
	(C)	Audio signal	(D)	Upper side frequency	
51.			total power	er radiated is 105 W. The power of	
	the carri	er is 85 W. What is modulation	n index?		
	(A)	0.685	(B)	0.587	
	(C)	0.586	(D)	0.865	

	(A)	Complexity	(B)	Bandwidth	
	(C)	Power	avoda ad (D)	Both (B) and (C)	
53.	What is	the intermediate frequen	cv of FM receiv	er?	
	(A)	Between 88 MHz and		er ? amozoaqon ons a 0 bas a 1 , gan 129 - 72)	
	(B)	Between 540 kHz and			
	.(C)	455 kHz	10+0 KHZ		
	(D)	10.70 MHz			
				inA (E)	
54.	What is	the frequency range for F	'M radio station	s?	
	(A)	100 MHz - 110 MHz	(B)	95 MHz-105 MHz	
	(C)	90 MHz - 110 MHz	(D)	88 MHz-108 MHz	
55.	For which	ch of the following mod	ulation techniq	ues, Radio Detector is used as	a
	demodul				
	(A)	FM Modulation	(B)	AM Modulation	
	(C)	DSBSC modulation	(D)	SSBSC modulation	
56.	What fur	action does the detector or o	discriminator in a	n AM or an FM receiver perform	?
	(A)	Detects the difference fr	requency from the	ne mixer	
	(B)	Changes the RF to IF			
	(C)	Recovers the audio sign	al		
	(D)	Maintains a constant IF	amplitude		
57.	Which o	f the following must be tru	ue in order to fair	thfully recover the signal from its	
	sampled	version?			
	(A)			ast twice the highest frequency	/
		component present in th			
	(B)			st twice the smallest frequency	1
		component present in th			
	(C)			ost twice the highest frequency	1
	~ ``	component present in th	e signal		
	(D)	None of the above			

52. Which of the following is/are the disadvantages of Amplitude Modulation?

58.	In which	of the following, Mu	ıltiphase switching si	ignals	s are required?	fthe following is/are the	
	(A)	PWM	(B)	PP			
	(C)	PAM	(D)	No	ne of the above	Power	
59.	In which	of the following, l's	and 0's are represen	ited b	y two different a	mplitudes ?	
٥,٠	(A)	ASK	(B)	PS			
	(C)	FSK	(D)	DP	SK		
60.	What is (A) (C)	the last block in PCl Sampler Encoder	M ? (B) (D)		ti-Aliasing Filter antizer		
	(C)	Lilcodei					
					(D)		
						ction does the detector or	
			152				
							(d) .
							(A)
					re signal,		
						component present in the	

1.	Time-de	elay and Phase can be measure	ed by	using a:
	(A)	VTVM	(B)	CRO
	(C)	TVM	(D)	PMMC
2.	The ext	ernal resistance inserted in th	e PM	MC circuit for increasing the
	range is	called:		
	(A)	Shunt resistance	(B)	Series resistance
	(C)	Multiplier	(D)	Both (A) and (C)
3.	The max	ximum current that can be safe	ly carr	ried in PMMC instruments is:
	(A)	10 mA	(B)	15 mA
	(C)	20 mA	(D)	25 mA
1.		asurements of capacitance and is used?	d Diel	ectric loss, which one of the
	(A)	Schering Bridges	(B)	Maxwells Bridge
	(C)	Maxwell wein Bridge	(D)	None of the above
5.	In Thern	nocouple instruments, which or	ne of th	ne following principle is used?
	(A)	Seeback effect	(B)	Peltier effect
	(C)	Johnson's effect	(D)	Both (A) and (B)
5 .	The 808	35 has :		
	(A)	16 address lines	(B)	32 address lines
	(C)	4 address lines	(D)	8 address lines
7.	Total m	emory which can be accessed	by In	tel-8085 is:
	(A)	2K bytes	(B)	4K bytes
	(C)	16K bytes	(D)	64K bytes
3.	In a mid stored in	croprocessor, the address of the	ne next	t instruction to be executed is
	(A)	Stack pointer	(B)	Address latch
	(C)	Program Counter	(D)	General Purpose Register
9.	In a 808 is:	5 Microprocessor, the status of	output	pins S ₀ , S ₁ for READ operation
	(A)	00	(B)	01
	(C)		(D)	11
CU	M-53712	_R		2
	111-00 / 12'			••••

10.	The CA	LL location (in Hexadecimal)	for T	RAP is :	
	(A)	0024	(B)	003C	
	(C)	0034	(D)	002C	
11.	Intel 82	55 is a :			
	(A)	Programmable Peripheral Inter	rface	(PPI)	
	(B)	Programmable DMA Controlle	er		
	(C)	Programmable Interrupt Contr	oller	(PIC)	
	(D)	None of the above			el Garriero
12.	Data are	e stored in the stack using:			
	(A)	FIFO	(B)	LIFO	
	(C)	Both (A) and (B)	(D)	None of the above	
13.	Subrout	ines are called by:			
	(A)	CALL instruction	(B)	JMP instruction	
	(C)	Shift	(D)	Push	
14.	A carrie	r is simultaneously modulated by	y two	Sine waves, using modulation	
	index of	f 0.4 and 0.3, the resultant mod	dulati	on index will be:	
	(A)	1.0	(B)	0.7	
	(C)	0.5	(D)	0.35	
15.		0% Amplitude Modulated signa	l, if	the total transmitted power is	
		carrier power will be:			
	(A)	2/3 P	(B)	1/2 P	
	(C)	1/3 P	(D)	1/4 P	
16.	-	ide Modulation is:	(D)	**********	
	(A)		(B)	Linear	
	(C)	Both Linear and Non-linear	(D)	Neither linear nor Non-linear	
17.	The me	st common detector used in an	A 1.4	radio brandanat manivar in	ž.
17.		Envelope detector used in an		Coherent detector	
	(A) (C)	Discriminator		Ratio detector	
	(0)	Discinimator	(D)	Railo delector	
CL	M-53712	-В		3	[Turn over

18.		row band FM system, the higher the of the system will be:	est m	odulating frequency is f _m . The
	(A)	6 f _m	(B)	f_{m}
	(C)	2 f _m	(D)	10 f _m
19.		dulating frequency in FM is i	ncrea	sed from 10 kHz to 20 kHz.
		ndwidth will get:	(D)	1-1-1
		doubled	. ,	halved
	(C)	increased by 20 kHz	(D)	increased tremendously
20.		ng is not an advantage of FM		
	(A)	Noise immunity		Fidelity
	(C)	Capture effect	(D)	Sputtering effect
21.	An angl	e modulated signal is given by	7	
	S(t)	$=\cos 2\pi (2 \times 10^6 t + 30 \sin 15^4)$	50t +	40 cos 150t).
	The max	ximum frequency and phase de	eviatio	ons of S(t) are:
	(A)	10.5 kHz, 14 π rad		(B) 6.0 kHz, 80 π rad
	(C)	10.5 kHz , $100 \pi \text{ rad}$		(D) 7.5 kHz, 100 π rad
22.	The PW	M needs:		
	(A)	more power than PPM		
	(B)	more samples per second than	n PPN	M
	(C)	more bandwidth than PPM		
	(D)	None of the above		
23.	In PCM	, the quantization noise depend	ds on	3
	(A)	Sampling rate	(B)	Number of Quantization levels
	(C)	Signal power	(D)	None of the above
24.	Which o	of the following modulation is	analo	og in nature ?
	(A)	PCM	(B)	DPCM
	(C)	DM	(D)	None of the above
25.	The ma	in objective of a 'Cell' in a Ce	ellula	r Mobile System is :
	(A)			Higher bandwidth
	(C)	Simple Modulation Technique		
	(C)	Simple Wodulation Technique	(D)	Hand on
CLI	M-53712-	-В		4.
		ar and a second		

26. If R₃ gets open circuited in Fig. 1; the reading across the ideal Voltmeter 'V' will be:

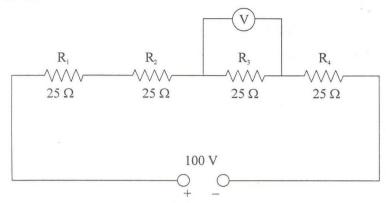
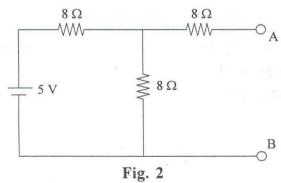


Fig. 1

(A) Fall to zero

- (B) Increase slightly
- (C) Decrease slightly
- (D) Equal to 100 volt
- 27. Current through a discharging capacitor exhibits:
 - (A) An exponential decaying function
 - (B) A linear function
 - (C) A step function
 - (D) None of these
- 28. In a series RLC circuit, at resonance:
 - (A) Current is minimum
- (B) Current is maximum
- (C) Impedance is maximum
- (D) None of these
- 29. The Thevenian equivalent resistance between terminals A and B in Fig. 2 is:



(A) 8 ohm

(B) 24 ohm

(C) 10 ohm

(D) 12 ohm

30.	Recombination	is	the	process	in	which	
		10	CIIC	Process	AAA	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	۰

- (A) An electron falls into a hole
- (B) A positive and a negative ion bond together
- (C) A valance electron becomes a conduction electron
- (D) All the above

31. The Depletion region consists of:

- (A) Minority carriers
- (B) Positive and negative ions
- (C) Majority carriers
- (D) None of the above

32. The value of DC voltage at the output of Half-wave rectifier with input $V \sin \omega t$ is :

(A) V

(B) $\frac{V}{\pi}$

(C) $\frac{2 \text{ V}}{\pi}$

(D) 0.707 V

33. An LED:

- (A) Emits light when reverse biased
- (B) Emits light when forward biased
- (C) Senses light when reverse biased
- (D) Acts as a variable resistance

34. If
$$I_{\scriptscriptstyle C}$$
 is 70 times greater than $I_{\scriptscriptstyle B},$ then β of transistor is :

(A) 0.7

(B) 0.35

(C) 70

(D) 700

35. When operating in cutoff and saturation regions, transistor acts like:

- (A) A linear amplifier
- (B) A switch
- (C) Variable capacitor
- (D) Variable resistance

36. The gate source voltage for JFET as shown in Fig. 3 (assuming $V_d = 7.0 \text{ V}$) is :

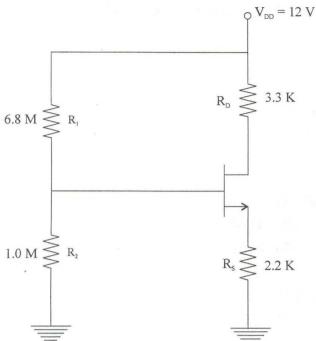


Fig. 3

(A) 1.52 V

(B) -5 V

(C) -1.8 V

- (D) 3.34 V
- 37. For a D-MOSFET, $I_{Dss} = 10.0$ mA and $V_{GS(off)} = -8.0$ V, the drain current for $V_{GS} = -3$ V is :
 - (A) 18.9 mA

(B) 3.91 mA

(C) 39.1 mA

- (D) .391 mA
- 38. One's complement of a binary number can be found by :
 - (A) Changing all 1's to 0's
 - (B) Changing all 0's to 1's
 - (C) Changing all 0's to 1's and all 1's to 0's
 - (D) Adding 1 to the obtained number after performing the action described at (C)
- 39. The expression for Sum function in case of a Half adder with inputs A and B:
 - (A) $Y = \overline{A \oplus B}$

(B) Y = A + B

(C) $Y = A \oplus B$

(D) Y = A.B

CLM-53712-B

7

[Turn over

40.	Which of	of the following Flip-Flop does	s not	have race-around problem ?
	(A)	T Flip-Flop	(B)	D Flip-Flop
	(C)	JK Flip-Flop	(D)	JK-Master Slave Flip-Flop
41.	A ring	counter is:		
	(A)	A combinational circuit		
	(B)	Circulating Shift Register		
	(C)	A Shift Register with feedbac	k	
	(D)	Both (B) and (C)		
42.	The gra	y code of a binary number 101	1 is	
	(A)	1011		1110
	(C)	1111	, ,	0001
	(0)		(D)	0001
43.	The par	ity of binary number 10011001	1 is	;
	(A)	Even	(B)	Odd
	(C)	4 .	(D)	5
44.	The nur	mber of Flip-Flops required for	Mod	dulo-10 counter is:
	(A)	10	(B)	3.35
	(C)	5	(D)	4
45.	The cou	inter requiring maximum numb	er of	Flip-Flops for a given MOD
	number			
	(A)	Ripple counter	(B)	BCD counter
		Ring counter		Programmable counter
46.	The ban	dwidth of an amplifier is deter	rmine	ed by :
	(A)	Mid range gain	(B)	The critical frequencies
	(C)	The roll-off rate	(D)	The input capacitance
47.	At uppe	er critical frequency, the output	volt	age of an amplifier is 10.0 V.
		ak voltage in midrange of ampl		-
	(A)			6.9 V
	(C)	14.14 V	(D)	10 V
CLI	M-53712	-B		8
				400

48.	Cross o	ver distortion occurs in	_ am	plifiers.	
	(A)	Push pull	(B)	Class A	
	(C)	Class AB	(D)	None	
19.	The max	ximum overall efficiency of a tra	nsfor	mer-coupled class-A amplifier	
	is:			•	
	(A)	78.5 %	(B)	25 %	
	(C)	85 %	(D)	50 %	
50.	Negativ	e feedback in amplifiers :			
	(A)	Lowers its lower cutoff frequency	ency		
	(B)	Raises its upper 3-dB frequen	су		
	(C)	Increases bandwidth			
	(D)	All the above			
51.	Shunt de	erived and series-fed feedback	in ar	amplifier:	
	(A)	Increases its output impedance	e		
	(B)	Decreases its output impedance	ce		
	(C)	Increases its input impedance		and the first of the second	
	(D)	Both (B) and (C)			
52.	A Collp	its oscillator uses:			
	(A)	Tapped coil	(B)	Inductive feedback	
	(C)	Tapped capacitance	(D)	Tapped resistance	
	×				
53.	The free	quency of oscillation of Phase	Shif	t oscillator with all the three	
		ce branches of phase shift net	work	equal to R and capacitance	
	branche	s equal to C is given by:			
	(A)	0.065/RC Hz	(B)	$1/\pi \sqrt{RC}$ Hz	
	(C)	$1/2\pi\sqrt{RC}$ Hz	(D)	None of these	
54.	The fee	dback element in an integrator	is:		
	(A)	Inductor	(B)	Resistor	
	(C)	Capacitor	(D)	Zener diode	
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56.	In a sca	ling adder, the input resistor	rs are:		
	(A)	All of same value			
	(B)	All of different value			
	(C)	Each proportional to weigh	at of its input		
	(D)	Related by a factor of 2			
57.	Slew ra	te of an operational amplifie	er is defined as:		*
	(A)	Maximum rate of change of	of output voltage		3
	(B)	Minimum rate of change o	f output voltage		
	(C)	Zero rate of change of out	put voltage		
	(D)	Average rate of change of	output voltage		
	100				
58.	The fund	ction of input attenuators in i	nstruments like VTM,	CRO etc. is to:	
	(A)	Increase input impedance			
	(B)	Attenuate the frequency ran	nge		
	(C)	Attenuate the input signal ar	nplitude without alterin	ng the frequency	
		contents			. 4
	(D)	Attenuate the input impeda	ince		
					4
59.	In a CR	T the highest positive poten	tial is given to:		
	(A)	Focusing Electrodes			
	(B)	Cathode			
	(C)	Vertical Deflection plates			
	(D)	Positive deflection accelera	ation anode		
60.	The res	olution of a digital Ammeter	r with 3-digit display	is:	
	(A)	1/10000	(B) 1/1000		
	(C)	1/4	(D) 1/3		
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			••••		

55. A triangular wave is applied to input of a differentiator, the output is :

(A) DC level

(C) Square wave

(B) Inverted triangular wave

(D) The first harmonic of triangular wave

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	below ce	ertain levels?		
	(A)	Limiter	(B)	Clamper
	(C)	IC voltage regulator	(D)	None of the above
5.		icon transistor, when a base-emit voltage drop of:	ter jur	nction is forward-biased, it has a
	(A)	0.7 V	(B)	0.3 V
	(C)	0.2 V	(D)	VCC
6.	Which o	of the following is true for an n-p-n	or p-n	-p transistor ?
	(A)	$I_E = I_B + I_C$	(B)	$I_B = I_C + I_E$
	(C)	$I_{C} = I_{B} + I_{E}$	(D)	None of the above
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An n-type semiconductor material:
 (A) Is intrinsic

(D) Requires no doping

electrons in intrinsic silicon?

(A) Bivalent

(C) Pentavalent

3. Doping of a semiconductor material means:

(B) Has trivalent impurity atoms added(C) Has pentavalent impurity atoms added

What types of impurity atoms are added to increase the number of conduction-band

(A) That a glue-type substance is added to hold the material together
 (B) That impurities are added to increase the resistance of the material
 (C) That impurities are added to decrease the resistance of the material

What type of diode circuit is used to clip off portions of signal voltages above or

(D) That all impurities are removed to get pure silicon

(B) Octavalent

(D) Trivalent

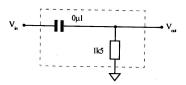
- 7. What type(s) of gate-to-source voltage(s) can a depletion MOSFET (D-MOSFET) operate with?
 - (A) Zero

(B) Positive

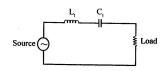
(C) Negative

- (D) Any of the above
- 8. If $V_{\rm D}$ is less than expected (normal) for a self-biased JFET circuit, then it could be caused by a(n):
 - (A) Open R_G

- (B) Open gate lead
- (C) FET internally open at gate
- (D) All of the above
- 9. Identify what type of filter this circuit is, and calculate its cutoff frequency:



- (A) Low-pass filter, $f_{cutoff} = 1.061 \text{ kHz}$
- (B) Band-pass filter, $f_{cutoff} = 2.061 \text{ kHz}$
- (C) High-pass filter, $f_{cutoff} = 1.061 \text{ kHz}$
- (D) All-pass filter, $f_{cutoff} = 2.061 \text{ kHz}$
- 10. What kind of filtering action does this resonant circuit provide?



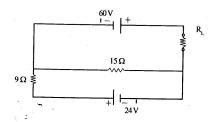
- (A) Band-pass filter
- (B) All-pass filter
- (C) High-pass filter
- (D) Low-pass filter

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11. Find the value of R_L for maximum power to R_L :



- (A) 5.625 ohms
- (B) 5.9 ohms
- (C) 6.125 ohms
- (D) 4.65 ohms

12.	Norton's Theorem is used	in a situation where the current through or the vol		
	across a load of	is the variable of interest.		

- (A) Varying values
- (B) Fixed values
- (C) Similar values
- (D) Two values
- 13. Which type of power amplifier is biased for operation at less than 180° of the cycle?
 - (A) Class A

(B) Class B or AB

(C) Class C

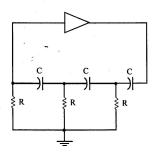
- (D) Class D
- 14. Which of the push-pull amplifiers is presently the most popular form of the class B power amplifier?
 - (A) Quasi-complementary
- (B) Transformer-coupled
- (C) Complementary-symmetry
- (D) None of the above

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- 15. Which of the following improvements is (are) a result of the negative feedback in a circuit?
 - (A) Lower output impedance
- (B) Reduced noise
- (C) More linear operation
- (D) All of the above
- 16. This circuit is a _____ oscillator.

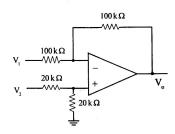


(A) Phase-shift

(B) Wien bridge

(C) Colpitts

- (D) Hartley
- 17. Determine the output voltage when $V_1 = -V_2 = 1 \text{ V}$:



(A) 0 V

(B) −2 V

(C) 1 V

(D) 2 V

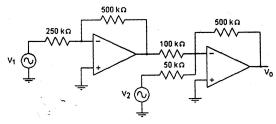
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18. Calculate the output voltage if $V_1 = V_2 = 700 \text{ mV}$:



(A) 0 V

(B) -12 V

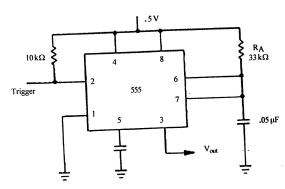
(C) 12 V

- (D) -8 V
- 19. What is the function of the comparators in the 555 timer circuit?
 - (A) To compare the output voltages to the internal voltage divider
 - (B) To compare the input voltages to the internal voltage divider
 - (C) To compare the output voltages to the external voltage divider
 - (D) To compare the input voltages to the external voltage divider
- 20. What is the output pulse width of the waveform at the output of the circuit in figure below?
 - (A) 1.65 ms

(B) 1.82 ms

(C) 4.98 ms

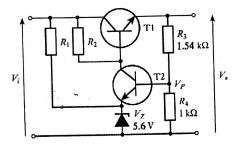
(D) 5.46 ms



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21. Determine the output voltage of the following regulator (assuming that the input voltage is sufficiently high to allow normal operation):



(A) 11 V

(B) 12 V

(C) 15 V

- (D) 16 V
- 22. Which of the following statements is incorrect?
 - (A) The output voltage of a switching regulator is controlled by altering the switching frequency
 - (B) A great advantage of switching regulators is that their power consumption is very low
 - (C) Switching regulators use switching speeds of 20 kHz or more
 - (D) Both bipolar transistors and FETs have very good switching characteristics
- 23. One of the most widely used forms of light sensor is the photodiode. Which of the following statements is correct?
 - (A) A photodiode is an example of a photoconductive sensor
 - (B) A photodiode can be used as either a photoconductive or a photovoltaic sensor
 - (C) A photodiode is an example of a photovoltaic sensor
 - (D) A photodiode is an example of a photoconductive and photovoltaic sensor
- 24. An LED is forward-biased. The diode should be on, but no light is showing. A possible trouble might be:
 - (A) The diode is open
 - (B) The series resistor is too small
 - (C) None. The diode should be off if forward-biased
 - (D) The power supply voltage is too high

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- (A) x < -2 or 2 < x or -1 < x < 1 (B) x < -2 or 2 < x

(C) -1 < x < 1

(D) $x \le -2 \text{ or } 2 \le x \text{ or } -1 \le x \le 1$

26. A sufficient condition that a triangle T be a right triangle is that $a^2 + b^2 = c^2$. An equivalent statement is:

- (A) If T is a right triangle then $a^2 + b^2 = c^2$
- (B) If $a^2 + b^2 = c^2$ then T is a right triangle
- (C) If $a^2 + b^2 6 \neq c^2$ then T is not a right triangle
- (D) T is a right triangle only if $a^2 + b^2 = c^2$

27. Using binary arithmetic, a number y is computed by taking the n-bit two's complement of x - c. If n is eleven, x = 101000010012 and c = 101012 then y = :

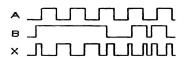
- (A) 011000011112
- (B) 011000011002
- (C) 011000111002
- (D) 010001111002

28. Consider the statement, "If n is divisible by 30 then n is divisible by 2 and by 3 and by 5". Which of the following statements is equivalent to this statement?

- (A) If n is not divisible by 30 then n is divisible by 2 or divisible by 3 or divisible by 5
- (B) If n is not divisible by 30 then n is not divisible by 2 or not divisible by 3 or not divisible by 5
- (C) If n is divisible by 2 and divisible by 3 and divisible by 5 then n is divisible by 30
- (D) If n is not divisible by 2 or not divisible by 3 or not divisible by 5 then n is not divisible by 30



- 29. As an engineer you are confronted with a TTL circuit board containing dozens of IC chips. You have taken several readings at numerous IC chips, but the readings are inconclusive because of their erratic nature. Of the possible faults listed, select the one that most probably is causing the problem:
 - (A) A defective IC chip that is drawing excessive current from the power supply
 - (B) A solar bridge between the inputs on the first IC chip on the board
 - (C) An open connection between the inputs on the first IC chip on the board
 - (D) A defective output IC chip that has an internal open to V_{cc}.
- 30. Which of the following is an important feature of the sum-of-products form of expressions?
 - (A) All logic circuits are reduced to nothing more than simple AND and OR gates
 - (B) The delay times are greatly reduced over other forms
 - (C) No signal must pass through more than two gates, not including inverters
 - (D) The maximum number of gates that any signal must pass through is reduced by a factor of two
- 31. The following waveform pattern is for a(n):



- (A) 2-input AND gate
- (B) 2-input OR gate
- (C) Exclusive-OR gate
- (D) None of the above

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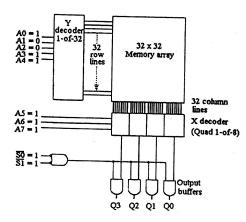
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- 32. Which of the following is the primary advantage of using the BCD code instead of straight binary coding?
 - (A) Fewer bits are required to represent a decimal number with the BCD code
 - (B) The relative ease of converting to and from decimal
 - (C) BCD codes are easily converted to hexadecimal codes
 - (D) BCD codes are easily converted to straight binary codes
- 33. For the given circuit, what memory location is being addressed?
 - (A) 10111 ~

(B) 249

(C) 5

(D) 157



- 34. How many flip-flops are in the 7475 IC?
 - (A) 1

(B) 2

(C) 4

- (D) 8
- 35. An RC circuit used in a nonretriggerable 74121 one-shot has an $R_{\rm EXT}$ of 49 Kilo Ohm and a $C_{\rm EXT}$ of 0.2 micro farad. The pulse width $(t_{\rm w})$ is approximately
 - (A) 6.9 micro second
- (B) 6.9 millisecond
- (C) 69 millisecond
- (D) 690 millisecond

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36.	To comp	oletely	y load and the	n unload an 8-bit r	egiste	r requires how many clock pulses?	,
	(A)	2			(B)	4	
	(C)	8			(D)	16	
37.				d at the interface		of an input port?	
	, ,		coder		` '	Latch	
	(C)	Tris	state buffer		(D)	None of the above	
38.	The suita	able t	orogrammabl	e counter for 808	6 mic	roprocessor is :	*
			3 chip			8254 chip	
	(C)		9 chip			8251 chip	
	` ′					r	
39.	What is	the a	ddress space	of 8086 CPU?			
	(A)	1M	В		(B)	256KB	
	(C)	1K	В		(D)	64KB	
40.				erent sizes as belo			
	1.		k × 4		2.	32 k × 16	
	3.		× 8		4	16 k × 4	
						st are Read/Write memory. What	
	micropr			nips or enip aio	ne cai	n map full address space of 8085	, ,
	(A)				(D)	1 only	ŧ
	(C)					4 only	·
	(0)	201	.11.9		(D)	Tonly	
41.	In an ins	truct	ion of 8085 n	nicroprocessor, h	ow m	any byte are present?	
	(A)	On	e or two		(B)	One, two or three	
	(C)	On	e only		(D)	Two or three	
42	I 0005	:					
42.	(A)	Tw		ow many interru		Three	
	(A) (C)					Five	
	(C)	1.00	1 1		(D)	rive	
43.	How ma	ny tir	nes will the fo	ollowing loop be	execu	ted:	
			LXIB	0010 H			
	LOC	P:	DCX	В			
			MOV	A, B			
			ORA	C			
				-			
			JNJ	LOOP			
	(A)	10			(B)	100	
	(C)	16			(D)	15	
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44	. If the	accumulator of an	intel 8085A microprod	cess	sor contains 37H and the previous
	opera	tion has set the carr	ry flag, the instruction	AC	156H will result in:
	(A			3)	
	(0) 7EH	1)))	84 H
45.	. Is ther	e any difference be	etween following decla	rat	ione ?
		extern int fun (·	ions ;
		int fun ();	,,		
	(A		cal		
	(B)	. 2		. . .	probably in another file
	(C)	int fun(): is over	rrided with extern int fi	, 18	probably in another file
	(D)		inded with extern int it	m(у ,
	(=)	Trone of these			
	#ind	clude <stdio.h> clude<math.h> main() float a=5.375; char *p; int i; p = (char *)&a for(i=0; i<=3; i+ printf("%02x'</math.h></stdio.h>	il be the output of the	pro	m is 0100 0000 1010 1100 0000 gram (on intel machine)?
	}	return 0;			
	(A)	40 AC 00 00	(B)	0.	4 CA 00 00
	(C)	00 00 AC 40	(D)		0 00 CA 04
17.	What we a[i][j][k]	ould be the equiva	lent pointer expression	n f	or referring the array element
	(A)	· · · · · · · · · · · · · · · · · · ·	(B)	*((*(*(*(a+i)+j)+k)+])
	(C)	(((a+i)+j)+k+l)			a+i)+j+k+l)
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	THE THEOLET			
int r	nain()			
{				
	float a=5.375;			
	char *p;			
	int i;			
	p = (char*)&a			
	for(i=0; i<=3; i++	-)		
	printf("%02x\r	n", (unsigned char)p[i]):
	return 0;		/F [-]	,,
}				
(A)	40 AC 00 00		(B)	04 CA 00 C
(C)	00 00 AC 40			00 00 CA 0
What we	ould be the equivale	ent pointer expre	essic	n for referrin
a[i][j][k]	[1]?			101 10101111
(A)	((((a+i)+j)+k)+l)	(B).	*(*(*(*(a+i)
(C)	(((a+i)+j)+k+l)			((a+i)+j+k+l
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```
int main ()
              int x;
              for(x=-1; x \le 10; x++)
                   if(x < 5)
                     continue;
                   else
                     break;
                  printf("IndiaBIX");
             return 0;
         (A) Infinite times
                                                (B) 11 times
         (C) 0 times
                                                (D) 10 times
49. Which of the following statements is correct about the following program?
         #include<stdio.h>
         int main()
            struct emp
               char name[25];
               int age;
               float sal;
            struct emp e[2];
            int i=0;
            for(i=0; i<2; i++)
              scanf("%s %d %f", e[i].name, &e[i].age, &e[i].sal);
            for(i=0; i<2; i++)
              scanf("%s %d %f", e[i].name, e[i].age, e[i]sal);
            return 0;
        (A) Error: scanf() function cannot be used for structures elements
        (B) The code runs successfully
        (C) Error: Floating point formats not linked abnormal program termination
        (D) Error: structure variable must be initialized
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                                                    13)
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48. How many times "IndiaBIX" is get printed?

#include<stdio.h>

```
50. What will be the output of the program?
          #include<stdio.h>
          int main()
              typedefint arr[5];
              arr iarr = \{1, 2, 3, 4, 5\};
              int i;
              for(i=0; i<4; i++)
               printf("%d,", iarr[i]);
          (A) 1, 2, 3, 4
          (B) 1, 2, 3, 4, 5
         (C) No output
         (D) Error: Cannot use typedef with an array
51. What is the purpose of "rb" in fopen() function used below in the code?
         FILE *fp;
      f<sub>p</sub> = fopen("source.txt", "rb");
         (A) Open "source.txt" in binary mode for reading
         (B) Open "source txt" in binary mode for reading and writing
         (C) Create a new file "source.txt" for reading and writing
         (D) None of the above
52. If the file 'source.txt' contains a line "Be my friend" which of the following will be the
      output of below program?
         #include<stdio.h>
         int main()
             FILE *fs, *ft;
             char c[10];
             fs=fopen("source.txt", "r");
             c[0] = getc(fs);
             fseek(fs, 0, SEEK END);
             fseek(fs, -3L, SEEK CUR);
             fgets(c, 5, fs);
             puts(c);
             return 0;
         (A) Friend
                                                (B) frien
         (C) end
                                                (D) Error in fseek();
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                                                    14)
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53.	What frequency range is used for FM radio transmission?						
	(A)	Very Low Frequency: 3 kHz to	o 30 kH	z			
	(B)	Low Frequency: 30 kHz to 30	0 kHz				
	(C)	High Frequency: 3 MHz to 30	MHz				
	(D)	Very High Frequency: 30 MH	Iz to 300) MHz			
54.	An exan	nple of an analog communication	method	is:			
	(A)	Laser beam	(B)	Microwave			
	(C)	Voice grade telephone line	(D)	All of the above			
55.	If the ba	ud rate is 400 for a QPSK signal	l, the bit	rate is bps.			
	(A)	100	(B)	400			
	(C)	800	(D)	1600			
56.	The con:	stellation diagram of 16-QAM h	as	_dots.			
	(A)	4	(B)	16			
	(C)	8	(D)	None of the above			
57.	For a	channel, the Nyquist bit rate	formula	defines the theoretical maximum	ı		
	bit rate.						
	(A)	Noisy		Noiseless			
	(C)	Bandpass	(D)	Low-pass			
58.		channel, we need to use the S	Shannor	capacity to find the maximum bit	t		
	rate.						
	(A)	Noisy	(B)				
	(C)	Bandpass	(D)	Low-pass			
59.	_		•	ower is P1 at the first point and P2	:		
		cond point. The dB is 0. This me	ans				
	(A)	P2 is zero		P2 equals P1			
	(C)	P2 is much larger than P1	(D)	P2 is much smaller than P1			
60.	If the bit	rate for an ASK signal is 1200 b	ps, the	baud rate is			
	(A)	300	(B)	400			
	(C)	600	(D)	1200			
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1.	1. The energy band in which free electrons exist is the:							
	(A)	First band	(B)	Second band				
	(C)	Conduction band	(D)	Valence band				
2.	Electro	n hole pairs are produced by:						
	(A)	Recombination	(B)	Thermal energy				
	(C)	Ionization	(D)	Doping				
3.	The ave	rage value of half wave rectified.	voltava	with a mark and a cooper				
	(A)	rage value of half-wave rectified v 63.7 V						
	(C)	141 V	(B)	127.3 V				
	(0)	141 V	(D)	0 V				
4.	Line reg	ulation is determined by:						
	(A)	Load current						
	(B)	Zener current and load current						
	(C)	Changes in load resistance and output voltage						
	(D)	Changes in output voltage and in		_				
5.	Collecte	or-feedback bias is :						
Э,		- •	0 11					
	(A)	Based on the principle of positiv	e teedt	oack				
	(B)	Based on β multiplication						
	(C)	Based on the principle of negative	ve feed	back				
	(D)	None of the above						
6.	In a cert	ain emitter follower circuit, the	curren	at gain is 50. The power gain is				
	approxim	nately:		Same to our rise power gain is				
		50 A _v	(B)	50				
	(C)	1	(D)					
	·		(-)	(1-) 1.12 (2)				
7.	The cons	tant current area of a FET lies be	tween :	:				
	(A)	Cutoff and saturation	(B)	Cutoff and pinch-off				
	(C)	0 and I _{pss}	(D)	Pinch-off and breakdown				
		p-10-00	• •					

8.	A MOSF	El differs from Jr El main	ly occause.	
	(A)	Of the power rating		
	(B)	The MOSFET has two ga	tes	
	(C)	The JFET has a pn junction	n	
	(D)	MOSFETs do not have a p	hysical chann	el
9.	Thevinin	's theorem can be used to tr	ansform a con	nplex network into an equivalent
	network			
	(A)	A voltage source in paralle	l with an equiv	valent resistance
	(B)	A voltage source in series	with an equiva	llent resistance
	(C)	A current source in paralle	l with an equiv	valent resistance
	(D)	A current source in series	with an equiva	lent resistance
10.	A series	LC resonance circuit has:		
	(A)	Maximum impedance at re	esonance frequ	iency
	(B)	Maximum current at resor	nance frequenc	cy
	(C)	Minimum impedance at re	esonance frequ	ency
	(D)	(B) and (C)		
11.	When th	e gain of the filter is minimu	ım at its centre	frequency, it is:
	(A)	A lowpass filter	(B)	A highpass filter
	(C)	A bandpass filter	(D)	A bandstop filter
12.	The qua	lity factor of a bandpass filt	er depends on	:
	(A)	The critical frequencies		
	(B)	Only on bandwidth		
	(C)	The center frequency and	the bandwidt	h
	(D)	Only on the centre freque	ncy	
13.	An amp	lifier that operates in the lin	ear region at al	
	(A)	Class A	(B)	Class AB
	(C)	Class B	(D)	Class C

:
couplin

21.	An SCR	can be	turned	off by	
	IMIDOIL	van oo	COLLIE CO	OLL OJ	,

- (A) Forced commutation
- (B) A negative pulse on the gate
- (C) Anode current interruption
- (D) (A) and (C)

22. The Diac is:

- (A) A thyristor
- (B) 'A bilateral two-terminal device
- (C) Like two parallel-4 layer diodes in reverse direction
- (D) All of the above

23. Which of the following is not a characteristic of the UJT?

- (A) Intrinsic standoff ratio
- (B) Negative resistance
- (C) Bilateral conduction
- (D) Peak-point voltage

24. The internal resistance of a photodiode:

- (A) Increases with light intensity when reverse-biased
- (B) Decreases with light intensity when reverse-biased
- (C) Increases with light intensity when forward-biased
- (D) Decreases with light intensity when forward-biased

25. According to De-Morgan's law, $\overline{A+BC}$ can be written as:

(A) A + BC

(B) A. BC

(C) A. BC

(D) None of the above

26. BCD representation of 85 is:

(A) 1000 0101

(B) 1100 0101

(C) 1000 0001

(D) 1001 0101

27. The logic function
$$f = \overline{(x.\overline{y}) + (\overline{x}.y)}$$
 is the same as:

- (A) $f = (x + y)(\overline{x} + \overline{y})$
- (B) $f = (\overline{x} + y)(x + \overline{y})$
- (C) $f = (x.y) + (\overline{x}.\overline{y})$
- (D) None of the above

28. The decimal equivalent of the Octal number (765)₈ is:

(A) 501

(B) 522

(C) 555

(D) 424

29). The lo	gic family with low power dissipat	ion is:	
	(A		(B) CMOS
	(C) DTL	(D	
			·	,
30	. ASCII	stands for:		
	(A)	American Standard Code for I	nforma	tion Interchange
	(B)	· American System Code for Inf		
	(C)			
	(D)			
21	Tt.	0.71		
31.		utput of 5-input XOR gate is high	when:	
	(A)	1	(B)	Even number of inputs are high
	(C)	Odd number of inputs are high	(D)	None of the above
32.	Gray co	ode for 101011 is :		
	(A)	101011	(B)	111110
	(C)	111101	(D)	110010
			(D)	110010
33.	JK FF c	an be transformed into TFF by:		
	(A)	Tying J and K	(B)	Inverting J
	(C)	Inverting K	(D)	None of the above
34.	The nun	ther of FFs required to decimal A		•
	(A)	nber of FFs required to design Mo 10		
	(C)	2	(B)	
	(0)	4	(D)	4
35.	1K bytes	of memory is equal to:		
	(A)	1000 bytes	(B)	1024 bytes
	(C)	1008 bytes	(D)	None of the above
			, ,	
36.	Master-s	lave FF is a modified version of:		
	(A)	JK FF	(B)	SR FF
	(C)	D FF	(D)	None of the above

31.		nas address bus of 14 bit wide and ldress bus is :	nence u	ne memory which can be accessed
	•	2 K bytes	(B)	32 K bytes
	` '	16 K bytes	(D)	•
	(C)	10 K bytes	(D)	
38.	In a micro	oprocessor, the address of the ne	xt instru	ction to be executed, is stored in:
	(A) .	Stack pointer	(B)	Address latch
	(C)	Program counter	(D)	General purpose register
39.	MOV D	x, Sx in 8085 μp is a:		
	(A)	Data transfer instruction	(B)	Control instruction
	(C)	Branching instruction	(D)	Machine instruction
40.	In an imr	mediate addressing mode, the va	lue of th	e operand is:
	(A)	Given in the instruction	(B)	Contained in a memory location
	(C)	Present at the port	(D)	None of the above
41.	An array	vis:		
	(A)	Collection of similar types of da	ata items	3
	(B)	Collection of different types of	data iter	ns
	(C)	Collection of float and integer v	alues	
	(D)	None of the above		
				_
42.		ne of the following controls the p		
	(A)	Switch	(B)	for
	(C)	while	(D)	All of the above
43.	A heade	r file ends with:		
	(A)	•	(B)	•
	(C)	,	(D)	None of the above
44.	Pointer	to pointer is a variable which sto	res:	
	(A)	The address of another pointer	variable	2
	(B)	The immediate data		
	(C)	Both float and integer data		
	(D)	Address of integer variables or	ıly	

- 45. In FM, modulation index m_f is equal to (Δf is the frequency deviation and f_m is the modulating signal frequency):

- (B) $\frac{\Delta f}{f_{\rm m}}$ (D) $\frac{1}{\Delta f f_{\rm m}}$
- 46. In an amplitude modulated system, the total power radiated 112.5 W. The power of the carrier is 100 W. What is modulation index?
 - (A) 1

(C) 0.75

- (D) None of the above
- 47. Analog Modulation scheme with lesser bandwidth requirement is:
 - (A) AM

(B) DSBSC

(C) SSBSC

- (D) VSB
- 48. Bandwidth of FM becomes equal to that of Am when:
 - (A) $\beta=1$

(B) $\beta = 0.5$

(C) $\beta = 0.1$

- (D) $\beta=10$
- 49. In TV transmission, picture signal is amplitude modulated and sound signal is frequency modulated. This is done because:
 - It is not possible to frequency modulate the picture signal
 - (B) Bandwidth requirement is minimized
 - Sound signal is more susceptible to noise than picture signal (C)
 - (D) Synchronization of picture frames becomes easier
- 50. A signal can be faithfully recovered from its sampled version if:
 - Sampling frequency is at least twice the highest frequency present in the signal
 - Sampling frequency is at least twice the smallest frequency present in the (B)
 - Sampling frequency is at most twice the highest frequency present in the (C) signal
 - (D) None of the above

51.	1's and 0	's are represented by two different	freque	encies in:
	(A)	ASK	(B)	PSK
	(C)	FSK	(D)	DPSK
52.	The erro	r in PCM can be reduced by:		
	(A)	By decreasing the number of quan	ıtizatic	on levels
	(B) ·	By increasing the number of quant	tizatio	n levels
	(C)	By increasing the Sampling freque	ency	
	(D)	By decreasing Sampling frequence	у	
53.	In PMM	C, damping force is provided by:		
	(A)	Eddy currents	(B)	Mechanical Friction
	(C)	Air	(D)	None of the above
54.	A swam	ping resistor is added in series with	n the co	oil of meters to avoid:
	(A)	Temperature error	(B)	Frequency error
	(C)	Parallex error	(D)	All of the above
55.	The valu	ne of multiplier resistor required to	desig	n a voltmeter of 10 V range with a
	PMMC	of internal resistance of 1 K Ω and	$I_{fsd} =$	100μA is:
	(A)	1 ΚΩ	(B)	9 ΚΩ
	(C)	10 ΚΩ	(D)	99 ΚΩ
56.	The valu	ne of external resistance at half scale	deflect	ion in case of series type ohmmeter
	is:			
	(A)	Half the internal resistance of the	meter	•
	(B)	The internal resistance of the me	ter	
	(C)	1/4th of the internal resistance of	the me	eter
	(D)	None of the above		
57.	Kelvin'	s double bridge is an extension of	:	
	(A)	Wheatstone bridge	(B)	Schering bridge
	(C)	Maxwell's bridge	(D)	Hay bridge

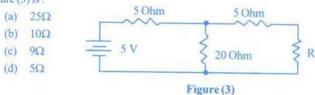
58.	To meas	sure using Lissasous Figures, CRO	O is op	erated in:
	(A)	XY mode	(B)	X5 mode
	(C)	TV mode	(D)	None of the above
59.	The purp	cose of the synchronizing control	in a CF	ROisto ·
	(A)	Focus the spot on the screen	(B)	_
	(C)	Adjust the amplitude of display	` '	Control the intensity of the spot
60.	Which or	fthe following is actuator:		
	(A)	Microphone	(B)	LVDT
	(C)	Piezoelectric transducer	(D)	Loudspeaker

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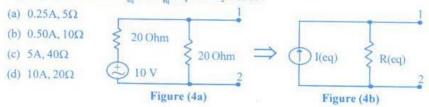
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1.	The curre	ent flowing $3K\Omega$ resistance in the	circuit	t given in Figure (1) will be:
	(a)	10 mA 2 k 0	Qhm	
	(b)	7 mA	\	
	(c)	4 mA = 20V		₹9V ₹ 3k Ohm
	(d)	3 mA		
			Figu	ure (1)
2.	The valu	e of h, and h, for the circuit shown	in Fig	gure (2) respectively are:
	(a)	10 ohm, -0.2 20 Ohm	2	20 Ohm
	(b)	20 ohm, -0.4	_~	M + 10 A
	(c)	30 ohm, -0.5 V	200	Ohm 20 Ohm V,
	(d)	40 ohm, -1.0	200	20 Onm 12
		•	F21	/2
2	A STERM	Maria Para Para	rigi	gure (2)
3.		nction diode is a	(LX)	Navadag dantas
		linear device		passive device
	(c)	unilateral device	(d)	active linear device
4.	Zener br	eakdown in a p-n junction results	due to	o:
	(a)	impact ionization	(b)	rupture of covalent bonds
	(c)	thermal instability	(d)	barrier lowering
5.	The dc a	nd ac load line of a transistor:		
	(a)	intersect with each other	(b)	have positive slope
	(c)	are parallel to each other	(d)	are parallel to voltage axis
6.	Identify	the false statement. The common of	collecto	or amplifier offers
		low output impedance		high voltage gain
		high input impedance		high current gain
7.	In case o	of MOSFET the voltage at which	the dra	ain current saturates is known as
		punch-through voltage		breakdown voltage
	(c)	pinch-off voltage		threshold voltage
8.	Which	of the following is not possible to f	abricat	te in IC technology?
	(a)	Resistor		(b) Capacitor
	(c)			(d) Inductor

 The value of the resistance R for maximum power transfer in the network shown in Figure (3) is:



 The circuit shown in Figure (4a) has the Norton equivalent circuit shown in Figure (4b). The value of I_{ss} and R_{ss} respectively will be:



- 11. The energy stored in a capacitor at any instant is given by :
 - (a) one half of the product of the capacitance and the square of the voltage across it at that instant
 - (b) the product of the capacitance and the square of the voltage across it at that instant
 - (c) one half of the product of the capacitance and the voltage across it at that instant
 - (d) the product of the capacitance and the voltage across it at that instant
- 12. The power factor is given by:
 - (a) peak power times 0.707
 - (b) the ratio of the true power to apparent power
 - (c) sine of the phase difference between voltage V and current I
 - (d) cos of the phase angle between true power and apparent power
- 13. A power amplifier has gain of 20dB and an input voltage level of 2mV. Assuming that the input and output impedances are the same. The voltage level at the amplifier output will be:
 - (a) 5 mV

(b) 10 mV

(c) 20 mV

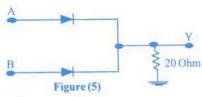
(d) 40 mV

14.	(s+b)	is the transfer function tha	t realizes the cl	aracteristics of a:	
		high pass filter		band pass filter	
	(c)	band reject filter	(d)	low pass filter	
15.	When 10	011, is multiplied by 101,	the result will I	se:	
	(a)	111101	(b)	111011	
	(c)	110111	(d)	111110	
16.	A two in	nput XOR gate has inputs	A and B , the or	tput of the gate is given by:	
	(a)	AB+AB	(b)	$\overline{A} B + A \overline{B}$	
	(c)	$A(\vec{A} + \vec{B})$	(d)	A B	
17.	The nun	nber of inputs and outputs	in a full adder	espectively are :	
	(a)	3 and 2	(b)	3 and 3	
	(c)	2 and 2	(d)	2 and I	
18.	The logi	cal expression $A + AB$ on	simplification	reduces to:	
	(a)	AB	(b)	A	
	(c)	A + B	(d)	В	
19.	Identify	the false statement from th	e following:		
	(a)	ECL gate do not satural	te		
	(b)	Complementary outputs	s are available v	vith ECL gate	
	(c)	The power dissipation in	n ECL logic gat	es is low relative to the other logic	
		families			
	(d)	Capacitive loading limit	s the fan out in	ECL gate	
20.	The gray	y code of the binary numb	er 101010 ₂ is:		
	(a)	010101,	(b)	010110,	
	(c)	111011,	(d)	1111112	
21.	The cha	racteristic values of power	r dissipation an	d propagation delay time for Low	
	power S	Schottky TTL devices are	respectively:		
	(a)	10mW, 10ns	(b)	15mW, 6ns	
	(c)	2mW, 10ns	(d)	100mW, 35ns	

22.			w R sets its ou	tput to, and a low S and
		ets its output to 0, 0	(1-)	1.0
		0, 1		1, 0
	(0)	0, 1	(d)	1, 1
23.	N numb	er of flip-flops connected i	n series divide	the clock frequency by a factor of:
		2 ^N		2 ^{N-1}
	(c)	2 ^{N+1}	(d)	N
24.	A mod-	10 counter can divide the	clock frequenc	y by a factor of:
	(a)	16	(b)	10
	(c)	4	(d)	2
25.	The may	kimum number of memor	ry locations tha	at an address bus with 16 bits can
	access is	:		
	(a)	16000	(b)	32536
	(c)	65536	(d)	60536
26.	The 815	6 is a 2,048 bit static RA	M with 256 wo	ords of 8 bits each. The number of
	address	lines this RAM has:		
	(a)	256	(b)	32
	(c)	16	(d)	8
27.	Identify	the correct statement from	the following:	
	(a)	It is much simpler to we	ork with dynan	nic RAMs than static RAMs with
		regard to design comple	xity of the RAM	M chips
	(b)	The static RAM contain same physical size	s more memor	y cells than dynamic RAM of the
	(c)		to refresh the	memory every few milliseconds
				SFET and capacitor are required.
28.	The Boo	blean expression (\overline{AB}) $\overline{(\overline{AB})}$	on simplifica	tion reduces to :
		A + B	120	$A \oplus B$
	(c)	AB	(d)	A(A+B)

29. The output of the circuit shown in Fig (5) will be given by:

- (a) Y = A + B
- (b) Y = A B
- (c) $Y = A \oplus B$
- (d) $Y = \overline{A} + \overline{B}$



30. Adding inverters to the inputs of an AND gate produces :

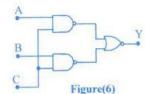
- (a) OR function
- (b) NOR function
- (c) Exclusive-OR function
- (d) XNOR function

31. Identify the false statement from the following:

- (a) ECL gate usually have complementary outputs
- (b) ECL gate has higher power requirements
- (e) ECL gate has higher noise margins than that of TTL
- (d) High speed operation is not possible in case of ECL gates because the transistors saturate in ECL gates.

32. The output Y of the circuit shown in Fig. (6) is given by:

- (a) Y = ABC
- (b) $Y = \overline{ABC}$
- (c) Y = ABC
- (d) Y = ABC



33. Ones complement of a binary number is found by:

- changing all zeros of the number to ones and all zeros of the number to zeros then adding 1 to the resultant number
- (b) changing all zeros of the number to ones and all ones of the number to
- (c) changing only all zeros of the number to ones
- (d) changing only all ones of the number to zeros

34. The number of restart instructions in $8085 \mu P$ is:

(a) 8

(b) 5

(c) 4

(d) 1

35.	The inp	ut pins of 8085 μP chip for th	e interrupt s	signal are from:
		Pins 11 to 15		Pins 6 to 10
	(c)	Pins 1 to 5		Pins 14 to 18
36.	On exec	ution of the following program	mme:	
		LH, !FFFH		
	INX	СН		
	MO	VA, H		
	AD	110H		
	STA	1000H		
	HLI			
	The con	tents of the memory location	1000H will	be:
		FFH		10 _H
	(c)	30 _H		2F _H
				**
37.	The sign	als carried by pins 29 and 33	of the 8085	5 μP respectively are:
	(a)	$\overline{WR}, \overline{RD}$		HOLD, HLDA
	(c)	S_{o} , S_{I}	(d)	RESETN, CLK
38.	If the cur	rent amplification factor α o	f a transisto	r is 0.99, the current amplification
	factor B	of the transistor will be:		, and a series and
	(a)	9	(b)	49
	(c)	79	(d)	99
39.	Foracon	nmon emitter configuration,	the collector	r current I for a given base current
39.	For a con	nmon emitter configuration, 1 by:	the collector	r current I _e for a given base current
39.	I _B is given	amon emitter configuration, by: $I_C = \beta I_B + I_{CBO}$		
39.	I _B is given (a)	i by:	(b)	r current I_c for a given base current $I_C = \beta I_B + (1 - I_{CBO})$ $I_C = \beta I_B + \beta I_{CBO}$
	I _B is giver (a) (c)	hby: $I_{C} = \beta I_{B} + I_{CBO}$ $I_{C} = \beta I_{B} + (1 + \beta)I_{CBO}$	(b) (d)	$I_{C} = \beta I_{B} + (1 - I_{CBO})$ $I_{C} = \beta I_{B} + \beta I_{CBO}$
	(a) (c) A transis	h by: $I_C = \beta I_B + I_{CBO}$ $I_C = \beta I_B + (1 + \beta)I_{CBO}$ tor having h-parameter h_{ie}	(b) (d) 5000Ω, h _{re}	$I_{C} = \beta I_{B} + (1 - I_{CBO})$ $I_{C} = \beta I_{B} + \beta I_{CBO}$ $= 1.6 \times 10^{-4}, h_{fe} = 56, h_{fe} = 50 \mu \text{A/V}.$
	(a) (c) A transis	h by: $I_C = \beta I_B + I_{CBO}$ $I_C = \beta I_B + (1 + \beta)I_{CBO}$ for having h-parameter $h_{ie} = 1$ and gain of the CE amplifier w	(b) (d) 5000Ω, h _{re}	$I_{C} = \beta I_{B} + (1 - I_{CBO})$ $I_{C} = \beta I_{B} + \beta I_{CBO}$ $= 1.6 \times 10^{-4}, h_{fe} = 56, h_{oe} = 50 \mu \text{A/V}.$ istance of 50K Ω will be:
	(a) (c) A transist	hby: $I_C = \beta I_B + I_{CBO}$ $I_C = \beta I_B + (1 + \beta)I_{CBO}$ for having h-parameter $h_{ie} =$ ant gain of the CE amplifier w -8	(b) (d) 5000Ω, h _{re} ith load resi	$I_{C} = \beta I_{B} + (1 - I_{CBO})$ $I_{C} = \beta I_{B} + \beta I_{CBO}$ $= 1.6 \times 10^{-4}, h_{fe} = 56, h_{fe} = 50 \mu \text{A/V}.$
40.	(a) (c) A transis: The curre (a) (c)	hby: $I_C = \beta I_B + I_{CBO}$ $I_C = \beta I_B + (1 + \beta)I_{CBO}$ for having h-parameter $h_{ie} =$ ant gain of the CE amplifier where -8 -32	(b) (d) 5000Ω, h _{re} ith load res (b) (d)	$I_{C} = \beta I_{B} + (1 - I_{CBO})$ $I_{C} = \beta I_{B} + \beta I_{CBO}$ =1.6×10 ⁻⁴ , $h_{fe} = 56$, $h_{oe} = 50 \mu \text{A/V}$ istance of 50K Ω will be: -16
40.	(a) (c) A transist The curre (a) (c) The decib	hby: $I_C = \beta I_B + I_{CBO}$ $I_C = \beta I_B + (1 + \beta)I_{CBO}$ for having h-parameter $h_{ie} =$ ant gain of the CE amplifier w -8	(b) (d) $5000\Omega, h_{re}$ with load results (b) (d) 100 is :	$I_{c} = \beta I_{B} + \beta I_{CBO}$ =1.6×10 ⁻⁴ , $h_{fe} = 56$, $h_{oe} = 50 \mu A/V$. istance of 50K Ω will be: -16

- 42. Identify the false statement from the following:
 - (a) In a Darlington amplifier configuration the output of one amplifier is coupled into the input of the next one by directly connecting emitter of one transistor to the base of the other transistor
 - (b) Darlington amplifier provides excellent characteristics of high input impedance and low output impedance
 - (c) Darlington amplifier provides low current gain
 - (d) Darlington amplifier is often used in high gain amplifiers because of its high current gain
- 43. How many different sets of input conditions of A, B, and C will produce a high output in the circuit shown in Figure (7)?
 - (a) 10
 - (b) 8
 - (c) 6
 - (d) 4

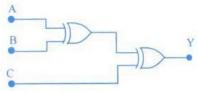


Figure (7)

- 44. In class-A amplifier when a transistor is driven from the edge of saturation region to cutoff, then for every 1W output power the power consumed internally is:
 - (a) 1 W

(b) 2 W

(c) 3 W

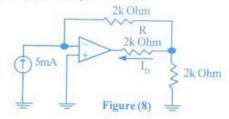
- (d) 4 W
- 45. The trans-conductance of a MOSFET is:
 - (a) independent of the drain current
 - (b) directly proportional to the drain current
 - (c) directly proportional to square root of the drain current
 - (d) inversely proportional to square root of the drain current
- 46. Unijunction transistor is a:
 - (a) variable capacitance device
- (b) relaxation oscillator
- (c) current controlled device
- (d) voltage controlled device

- 47. Identify the correct statement from the following. In an RC coupled amplifier:
 - the low frequency response is affected by junction capacitances and high frequency response is affected by coupling capacitor
 - (b) only high frequency response is affected by coupling and bypass capacitors
 - (c) the low frequency response is affected by coupling and bypass capacitors
 - (d) the coupling capacitor do not affect the frequency
- 48. Class-B push-pull amplifiers there exists
 - (a) intermodulation distortion
 - (b) cross-over distortion
 - (c) even harmonic distortion
 - (d) neither even harmonic nor odd harmonic distortion
- 49. The maximum theoretical efficiency of an amplifier in class-B operation is
 - (a) 78.5%

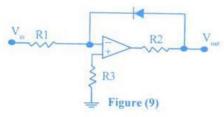
(b) 50.5 %

(c) 40.5 %

- (d) 25.5 %
- If the emitter resistance of a common emitter amplifier is not bypassed by a capacitor the emitter resistance provides a:
 - (a) Negative voltage feedback
- (b) Current series feedback
- (c) Voltage shunt feedback
- (d) Positive current feedback
- 51. The current I_D in circuit shown in Figure (8) will be equal to:
 - (a) 5mA
 - (b) 10mA
 - (c) 15mA
 - (d) 20mA



- 52. The circuit shown in Figure (9) is a:
 - (a) Logarithmic amplifier
 - (b) Differentiator
 - (c) Antilogarithmic amplifier
 - (d) Integrator



	A CONTRACTOR OF THE CONTRACTOR	oo and rec	aback fraction p is 0.03, the 100p		
(a)	3	(b)	30		
(c)	90	(d)	100		
transistor	If $C_{\rm BE}$ and $C_{\rm CB}$ represent the base-emitter and collector-base capacitances of a transistor respectively. If the transistor is employed in common emitter amplifier having voltage gain A, the input capacitance $C_{\rm in}$ of the amplifiers is given by:				
(a)	$C_{in} = C_{BE} + AC_{CB}$	(b)	$C^{10} = C^{BE} + C^{CB}$		
(c)	$C_{in} = C_{BE} + (1 + A)C_{CB}$	(d)	$C_{in} = C_{CB} + (1+A)C_{BE}$		
Whicho	f the following pin pairs in 741	Op Amp IC	are for power supply connections?		
(a)	2 and 3	(b)	6 and 8		
(c)	1 and 5	(d)	7 and 4		
Identify	the false statement. The ideal	Op Amp w	ould exhibit:		
(a)	Infinite voltage gain				
(b)	Infinite input resistance				
(c)	Zero output voltage when ir	put voltage	e is zero		
(d)	Infinite output resistance				
The min	imum quantity that an instrum	ient can me	asure is known as:		
(a)	Precision	(b)	Resolution		
(c)	Accuracy	(d)	Sensitivity		
The rela	tive limiting error of product	of two term	s is equal to the:		
(a)	sum of the of the relative er	ror of the to	erms		
(b)	difference of the relative en	ror of the te	rms		
(c)	division of the relative error	r of the term	ns		
(d)	product of the relative error	r of the term	ns		
the inpu	its V ₁ and V ₂ of the amplifier a	ce mode ga are 1.0mV a	$\sin A_{\rm vp} = 1000$ and CMMR=100. If and 0.9mV respectively, the output		
(a)	10.95 mV	(b)	20.95 mV		
	100 5 1/	(4)	1095 mV		
(c)	109.5 mV	(4)	10951114		
	gain of the (a) (c) If C _{BE} and transistor voltage g (a) (c) Which or (a) (c) Identify (a) (b) (c) (d) The min (a) (c) The rela (a) (b) (c) (d) In a diff the inpurvoltage	gain of the amplifier is: (a) 3 (c) 90 If C_{BE} and C_{CB} represent the base-entransistor respectively. If the transistor is voltage gain A, the input capacitance (a) $C_{im} = C_{BE} + AC_{CB}$ (c) $C_{im} = C_{BE} + (1 + A)C_{CB}$ Which of the following pin pairs in 741 (a) 2 and 3 (c) 1 and 5 Identify the false statement. The ideal (a) Infinite voltage gain (b) Infinite input resistance (c) Zero output voltage when in (d) Infinite output resistance The minimum quantity that an instrum (a) Precision (c) Accuracy The relative limiting error of product (a) sum of the of the relative error (d) product of the relative error (d)	(a) 3 (b) (c) 90 (d) If C_{BE} and C_{CB} represent the base-emitter and of transistor respectively. If the transistor is employed in voltage gain A, the input capacitance C_{in} of the and (a) $C_{in} = C_{BE} + AC_{CB}$ (b) (c) $C_{in} = C_{BE} + AC_{CB}$ (d) Which of the following pin pairs in 741 Op Amp IC (a) 2 and 3 (b) (c) 1 and 5 (d) Identify the false statement. The ideal Op Amp were (a) Infinite voltage gain (b) Infinite input resistance (c) Zero output voltage when input voltage (d) Infinite output resistance The minimum quantity that an instrument can mere (a) Precision (b) (c) Accuracy (d) The relative limiting error of product of two terms (a) sum of the of the relative error of the terms (b) difference of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the relative error of the terms (d) product of the amplifier are 1.0 mV avoltage of the amplifier will be:		

- 60. A moving coil galvanometer is converted into a DC ammeter by connecting :
 - (a) a capacitor of appropriate capacitance across the galvanometer
 - (b) a resistor of appropriate resistance across the galvanometer
 - (c) a resistor of appropriate resistance in series with galvanometer
 - (d) an inductor of appropriate inductance across the galvanometer



ELECTRONICS

1.	seco	bridge-type full-wave rectifier, if V_m is the peak voltage across the ndary of the transformer, the maximum voltage coming across each reversed diode is :
	(a)	\mathbf{v}_{m}
	(b)	2 V _m
533	(e)	$\frac{1}{2}V_m$
	(d)	$V_m / \sqrt{2}$
2.	Whi	ch of the following is a unipolar device?
	(a)	P-N junction diode
	(b)	Zener diode
	(c)	Tunnel diode
	(d)	Schottky diode
3.	Low	est output resistance is obtained in :
	(a)	CB
	(b)	CE
	(c)	cc
	(d)	both (a) and (b)
4.	In t	he case of BJT amplifier, bias stability is achieved by :
	(a)	keeping the base current constant
	(b)	keeping $I_{\rm C}$ and $V_{\rm CE}$ constant irrespective of the undesired changes in base current
	(c)	keeping the temperature constant
	(d)	keeping the temperature and base current constant
5.	JFE	T has main drawback of :
	(a)	having low input impedance
	(b)	having high output impedance
	(c)	being noisy
	(d)	having small gain-bandwidth product
Elect	ronics	5

6.	The	most popular form of IC package is :
	(a)	TO-5
X	(b)	DIL
	(c)	Flat Pack
	(d)	All of the above
7.	Апе	twork is said to be non-linear if it does not satisfy:
	(a)	homogenity condition
	(b)	superposition condition
	(c)	both (a) and (b)
	(d)	associative condition
8.	The	superposition theorem is applicable to :
	(a)	linear, non-linear and time variant responses
	(b)	linear and non-linear resistors only
	(c)	linear responses only
	(d)	none of the above
9.	Selec	tivities of different resonance circuits are compared in terms of their :
	(a)	impedances
	(b)	reactances
	(c)	frequencies
	(d)	bandwidths
10.	The	dual of a loop is:
	(a)	twig
	(b)	node
	(c)	mesh
	(d)	tree
Elect	ronics	2

11.		uare wave with a period of 10 µs drives a T flip-flop. The period of the ut signal will be :		
	(a)	100 µs		
	(b)	20 μs		
	(c)	10 μs		
	(d)	5 µs		
12.		e is the fastest unsaturated logic gate has the excellent immunity.		
	(a)	ECL, TTL		
	(b)	TTL, ECL		
	(c)	ECL, HTL		
	(d)	RTL, DTL		
13.	The ASCII is a 7-bit code for :			
	(a)	letters		
	(b)	numbers		
	(c)	other symbols		
	(d)	all of the above		
14.	Odd	parity of wood can be conveniently tested by :		
	(a)	XOR gate		
	(p)	OR gate		
	(c)	XNOR gate		
	(d)	NAND		
15.	A multiplexer is known as :			
	(a)	multivibrator		
	(b)	data selector		
	(c)	decoder		
	(d)	seven segment display		

16.		which of the following flip-flop the output is clearly defined for all derations of two inputs?
	(a)	D
	(b)	RS .
	(c)	JK
	(d)	T
17 .	A cor	mplete microcomputer system consists of :
	(a)	microprocessor
	(b)	memory
	(c)	add-ons
	(d)	all of the above
18.	The	most common addressing techniques employed by a CPU is :
	(a)	immediate
	(b)	direct
	(c)	indirect
	(d)	all of the above
19.	Whic	h of the following is the user programmed semiconductor memory?
	(a)	SRAM
	(b)	DRAM
	(c)	EPROM
	(d)	All of the above
20.	For a	a memory system, the cycle time is :
	(a)	same as the access time
	(b)	longer than the access time
	(c)	shorter than the access time
	(d)	none of the above
Elect	ronics	4

21.		programming language, which of the following type of operators enjoys est precedence:	
	(a)	relational operators	
	(b)	equality operator	
	(c)	logical operators	
	(d)	arithmetic operators	
22.	The	single character input/output functions are :	
	(a)	scanf() and printf()	
	(b)	getchar() and printf()	
	(c)	scanf() and putchar()	
	(d)	getchar() and putchar()	
23.	The	two statements that can be used to change the flow of control are :	
	(a)	if and switch	
	(b)	if and while	
	(c)	switch and do-while	
	(d)	break and continue	
24.	The	comma operator (,) is primarily used in conjunction with :	
	(a)	for statement	
	(b)	if-else statement	
	(c)	do-while statement	
	(d)	all of the above	
25.	Arrays that do not have their dimensions explicitly specified are called :		
	(a)	unsized arrays	
	(b)	undimensional arrays	
	(c)	initialized arrays	
	(d)	no size of arrays	

Elect	tronics	6
-15 15	(d)	forward and backward transversal within the list is permitted
	(c)	components are arranged hierarchically
	(b)	there is no beginning and no end
	(a)	components are all linked together in some sequential manner
30.		nked lists with multiple pointers:
616	(d)	None of the above
	(c)	Linked list with multiple pointers
	(b)	Circular linked list
	(a)	Linear linked list
29 .	Whic	h of the following is not a linked data structure?
	(d)	all have the same type
	(c)	are grouped neat to each other in memory
	(b)	must be structures
	(a)	all occupy the same space in memory
28.	A un	ion consists of a number of elements that :
	(d)	union
	(c)	structure
	(b)	typedef
	(a)	pointer
	to ex	isting data types is:
27 .		feature that allows you to define new data types that are equivalent
	(d)	% and &
	(c)	& and &&
	(b)	* and &&
	(a)	* and &

C contains two special pointer operators:

26.

31,		th of the following parameters is used for distinguishing between a small and a large signal amplifier?
	(a)	Voltage gain
	(b)	Frequency response
	(c)	Harmonic distortion
	(d)	Input/output impedances
32.	Class	AB operation is often used in power amplifiers in order to :
	(a)	get maximum efficiency
	(b)	remove even harmonics
	(c)	over come crossover distortion
	(d)	reduce collector dissipation
33.	A th	yristor is a semiconductor switch which is :
	(a)	unilateral and astable
	(b)	bilateral and astable
	(c)	unilateral and bistable
	(d)	bilateral and bistable
34.	The	crystal oscillator frequency is very stable due to :
	(a)	rigidity of crystal
	(b)	size of crystal
	(e)	structure of crystal
	(d)	high Q of the crystal
35.		requirement of an oscillator using positive feedback amplifier as an ator, is that:
	(a)	there must be positive feedback
	(b)	initially the value of loop gain AB must be greater than unity
	(c)	after the desired level is reached the loop gain AB must decrease to unity

(d)

all of the above

	(a)	sine wave
	(b)	square wave
	(c)	saw tooth wave
	(d)	trapezoidal
37.	Most	of the linear ICs are based on the two transistor differential amplifier
	becar	use of its:
*	(a)	input voltage dependent linear transfer characteristic
	(b)	high voltage gain
	(c)	high input resistance
	(d)	high CMRR
38.	The	type of multivibrator used for generation of clock pulses is:
	(a)	monostable multivibrator
	(b)	astable multivibrator
	(c)	bistable multivibrator
	(d)	none of the above
39.	The	material used for the construction of LED is :
	(a)	Si
	(b)	Ge
	(c)	GaAsP
	(d)	None of the above
40.	Whie	ch of the following is not classified as a photoconductive device?
	(a)	a photovoltaic cell
	(b)	a PIN photodiode
	(e)	a phototransistor
	(d)	a light dependent resistor
Float	ronics	8
21001	1011100	

36. UJT when used for triggering an SCR has waveform :

41.	Electronic voltmeter provides more accurate readings in high resistance circuits as compared to a non-electronic voltmeter because of:
	(a) high V/ohm ratings
	(b) high ohm/V ratings
	(c) low meter resistance
	(d) high resolution
42.	In a CRT the length l of the magnetic field in the initial direction of the electron beam when compared with the radius of curvature of that beam is:
	(a) very large
	(b) very small
	(c) equal
	(d) negligibly small
43.	The Miller sweep circuit normally used in a CRO is basically:
	(a) voltage to current converter circuit
	(b) a current to voltage converter circuit
	(c) an integrator circuit
	(d) a differentiator
44.	The disadvantage of Maxwell's bridge is that:
	(a) inductance measurement is frequency dependent
	(b) it cannot be used to measure inductance for large values of Q
	(c) both inductance and Q cannot be measured
	(d) resistance of the inductor measurement is frequency dependent
45.	What type of bridge is recommended for measuring resistances less that 1 ohm?
	(a) Wheatstone bridge
	(b) Schering bridge
	(c) Maxwell bridge

(c) (d)

Kelvin bridge

46.	A voltmeter has 100 divisions on 0-100 V range. One-tenth of each division
979T.A	can be read with certainty. The resolution of the meter is :
	(a) 0.1 V
	(b) 0.01 V
	(c) 1.0 V
	(d) 1.01 V
47.	The resistance of a strain gauge should be high:
	(a) to increase sensitivity
	(b) to reduce hysteresis effects
	(c) to swamp out the effects of variations of resistance in other parts of
	the bridge
	(d) none of the above
48.	Piezo electric transducers are :
	(a) active transducers
	(b) passive transducers
	(c) secondary transducers
	(d) none of the above
49 .	The resolution of a digital ammeter with 3-digit display is :
	(a) 1/2
*2	(b) 1/3
	(c) 1/8
	(d) 1/4
50.	A set of independent current measurements were taken and recorded as follows
	12.8 A, 12.2 A, 12.5 A, 13.1 A, 12.9 A and 12.4 A. The standard deviation
	is:
100	(a) 0.283 A
	(b) 0.300 A
	(c) 0.399 A

10

0.414 A

(d)

- 51. In a 100% amplitude modulated signal, if the total transmitted power is P, then carrier power will be:
 - (a) $\frac{2}{3}$ F
 - (b) $\frac{1}{2}$ P
 - (c) $\frac{1}{3}$ P
 - (d) $\frac{1}{4}$ F
- 52. In a narrow band FM system, the highest modulating frequency is f_m . The bandwidth of the system will be:
 - (a) $6 f_m$
 - (b) f_m
 - (c) $2 f_m$
 - (d) 10 f_m
- 53. In TV transmission, picture signal is amplitude modulated and sound signal is frequency modulated. This is done because:
 - (a) it is not possible to frequency modulate the picture signal
 - (b) bandwidth requirement is minimised
 - (c) sound signal is more susceptible to noise than picture signal
 - (d) synchronisation of picture frames becomes easier
- 54. The most common detector used in an AM radio broadcast receiver is :
 - (a) envelope detector
 - (b) coherent detector
 - (c) discriminator
 - (d) ratio detector
- 55. The main advantage of PCM system is :
 - (a) lower bandwidth
 - (b) lower power
 - (c) lower noise
 - (d) none of the above

56.	Pulse	communication system that is inherently highly immune to noise is:
	(a)	PAM
	(b)	PWM
	(c)	PPM
100	(d)	PCM ·
57.	Which	n of the following antenna gives circular polarization?
50	(a)	Yagi-uda
	(b)	Parabolic
	(c)	Dipole
	(d)	Helical
58.	The g	round wave eventually disappears as one moves from transmitter because
	of:	
	(a)	surface attenuation
	(b)	diffraction
	(c)	loss of line of sight
	(d)	tilting
59 .	Whic	ch of the following statements is not valid for FM systems?
	(a)	It needs less bandwidth
	(b)	It offers better S/N ratio
	(c)	It requires less modulating power
	(d)	All of the above
60.	In a	TV which of the following stages has AGC bias?
	(a)	Mixer
	(b)	Local oscillator
25	(c)	RF amplifier
	(d)	AFT discriminator
Elec	tronics	12

Electronics

ELECTRONICS

- A differential amplifier has common-mode gain of 0.02 db and differential-mode gain of 200 db. Its CMMR in db is:
 - (A) 0.02 db
 - (B) 4.80 db
 - (C) 80.0 db
 - (D) 200.0 db
- 2. If the cut-in voltage for silicon diodes D_1 and D_2 used in the circuit shown in Fig.(1) is 0.6 V, the output voltage V_0 for $V_1 = 5$ V and $V_2 = 5$ V is :

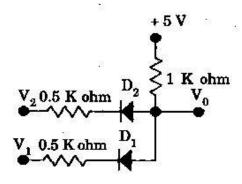


Fig. (1)

- (A) 0 V
- (B) 5 V
- (C) 10 V
- (D) 15 V
- 3. Identify the true statement. An emitter follower has :
 - (A) low input impedance and high voltage gain
 - (B) high output impedance and unity current gain
 - (C) low input impedance and unity current gain
 - (D) high input impedance and unity voltage gain

- 4. Bridge rectifiers are preferred because :
 - (A) ripple factor of the bridge rectifier is less than that of centre-tap fullwave rectifier
 - (B) PIV in case of bridge rectifier is half that of a centre-tap full-wave rectifier
 - (C) the regulation in case of bridge rectifiers is higher than that in case of centre-tap full-wave rectifier
 - (D) the rectification efficiency is larger than that in case of centre-tap fullwave rectifier
- 5. In a p-n junction the Zener breakdown is caused by :
 - (A) field ionization
 - (B) impact ionization
 - (C) thermal runaway
 - (D) punchthrough mechanism
- 6. Identify the true statement. In case of avalanche breakdown of a p-n junction:
 - (A) direct band rupture occurs due to high electric field
 - (B) the charge carriers acquire high energies sufficient to produce electronhole pairs by impact ionization
 - (C) electron-hole pairs are generated because of the increase in junction temperature
 - (D) negligible current flows across the junction
- 7. A transistor is said to be in saturation region when :
 - (A) emitter-base junction is forward biased and collector-base junction is reverse biased
 - (B) both emitter-base junction and collector-base junction are reverse biased
 - (C) both emitter-base junction and collector-base junction are forward biased
 - (D) emitter base-junction is reverse biased and collector-base junction is forward biased

	(A)	degenerate semiconductors
	(B)	non-degenerate semiconductors
	(C)	compensated semiconductors
100	(D)	intrinsic semiconductors
9.	In ca	se of a MOSFET the drain-source voltage at which the drain current
	becom	nes nearly constant is called :
	(A)	punchthrough voltage
	(B)	cut-in voltage
	(C)	early voltage
	(D)	pinch-off voltage
10.	The 1	use of a bypass capacitor across emitter resistor in transistor circuits is
	to:	26
	(A)	avoid shift in the Q-point
	(B)	stabilize the circuit against temperature variations
	(C)	avoid loss of signal gain
	(D)	stabilize the circuit against the variation in β
11.	For a	a p-n-p transistor if $\alpha = 0.98$ and $I_{CBO} = 5 \mu A$, then for a base curren
		00 μA the collector current I _C is :
	(A)	1.50 mA
	(B)	2.50 mA
	(C)	3.15 mA
	(D)	5.15 mA
12.	The	voltage gain of a source follower employing FET is usually:
	(A)	slightly less than unity but positive.
	(B)	equal to unity but negative.
	(C)	never less than +200.
80	(D)	slightly greater than unity but negative
MENNEY :	ronics	3 P.T.C

Semiconductors having Fermi level within the allowed bands are known as :

8.

- 13. Under thermal equilibrium the product of the electron and hole carrier concentrations in a semiconductor is:
 - (A) dependent on the doping concentrations
 - (B) independent on the doping concentrations
 - (C) greater than square of the intrinsic concentrations
 - (D) less than square of the intrinsic concentrations
- 14. The Schottky diode clamping across the collector-base junction of the transistor in case of Schottky-TTL is used:
 - (A) to increase the current gain of the transistor
 - (B) to prevent transistor from junction breakdown
 - (C) to prevent transistor from saturation
 - (D) to prevent transistor from thermal runaway
- 15. According to the De Morgan's theorem :
 - (A) An n-input NAND gate is equivalent to an n-input bubbled AND gate
 - (B) An n-input OR gate is equivalent to an n-input bubbled AND gate
 - (C) OR gate and NOR gate are complement to each other
 - (D) An n-input NAND gate is equivalent to n-input bubbled OR-gate
- 16. The output logic Y of the circuit shown in Fig. (2) is :

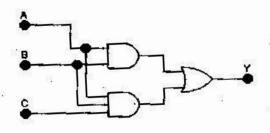


Fig. (2)

- (A) ABC
- (B) AB
- (C) AC
- (D) A

- 17. The number of load gates that a logic device can drive reliably is called the :
 - (A) fan-out
 - (B) fan-in
 - (C) standard load
 - (D) current sink
- 18. The potential divider method of biasing in translator amplifiers is used as

it

- (A) increases the voltage gain of the amplifier
- (B) makes the operating point stable against the variations of β
- (C) reduces the noise of the amplifier
- (D) prevents transistor from thermal run away
- 19. The equivalent resistance between A and B terminals of the circuit shown in Fig. (3) is:

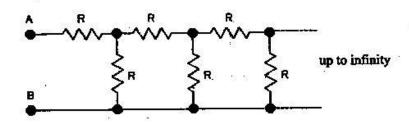


Fig. (3)

- (A) R
- (B) 2R
- (C) $(1 + \sqrt{5})R$
- (D) $(1 + \sqrt{10})R$

- 20. For a step voltage input an integrator produces:
 - (A) a sine wave
 - (B) a square wave
 - (C) a narrow spike
 - (D) a ramp
- 21. For the circuit shown in Fig. (4) the output $V_{\rm out}$ will be :

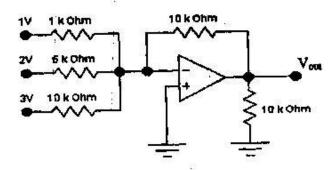


Fig. (4)

- (A) -17 V
- (B) -15 V
- (C) -9.6 V
- (D) -6 V
- 22. The resolution of 4-digit 0-10 V DVM is:
 - (A) 1 V
 - (B) 1 mV
 - (C) 1 µV
 - (D) 1 pV

23. For an input voltage $V_{in} = 10 \sin (2000 \ t) \mu V$ the output voltage V_{out} for the circuit shown in Fig. (5) will be:

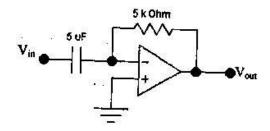


Fig. (5)

- (A) $-100 \cos (2000 t) \mu V$
- (B) $-100 \sin (2000 t) \mu V$
- (C) $-500 \cos (2000 t) \mu V$
- (D) $-500 \sin (2000 t) \mu V$
- 24. One of the following devices has no negative region in its static I-V characteristics. The device is:
 - (A) Thyristor
 - (B) Tunnel diode
 - (C) Gunn diode
 - (D) Zener diode
- 25. If the data stored at memory locations 0800 and 0801 is $2C_{\rm H}$ and $51_{\rm H}$ respectively, then on execution of the program :

LDA 0800

MOV B,A

LDA 0801

ADD B

STA 0802

the contents of the memory location 0802 will be :

- (A) 7D_u
- (B) 7E_H
- (C) 20_H
- (D) 51_H

 (A) one, direct (B) two, register (C) three, direct (D) two, intermediate Early voltage is usually determined from the : (A) input characteristics of CE transistor (B) input characteristics of CB transistor (C) output characteristics of CB transistor (D) output characteristics of CE transistor if the current gain α of a transistor is 0.99, the current gain β of the transistor will be : (A) 49.0 (B) 50.0
 (B) two, register (C) three, direct (D) two, intermediate Early voltage is usually determined from the: (A) input characteristics of CE transistor (B) input characteristics of CB transistor (C) output characteristics of CB transistor (D) output characteristics of CE transistor If the current gain α of a transistor is 0.99, the current gain β of the transistor will be: (A) 49.0
 (C) three, direct (D) two, intermediate Early voltage is usually determined from the: (A) input characteristics of CE transistor (B) input characteristics of CB transistor (C) output characteristics of CB transistor (D) output characteristics of CE transistor If the current gain α of a transistor is 0.99, the current gain β of the transistor will be: (A) 49.0
 (D) two, intermediate Early voltage is usually determined from the: (A) input characteristics of CE transistor (B) input characteristics of CB transistor (C) output characteristics of CB transistor (D) output characteristics of CE transistor If the current gain α of a transistor is 0.99, the current gain β of the transistor will be: (A) 49.0
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(D) output characteristics of CE transistor If the current gain α of a transistor is 0.99, the current gain β of the transistor will be : (A) 49.0
If the current gain α of a transistor is 0.99, the current gain β of the transistor will be : (A) 49.0
will be: (A) 49.0
(A) 49.0
900 H N D D D D D D D D D D D D D D D D D D
(B) 50.0
(C) 69.0
(D) 99.0
The maximum frequency of oscillation of a Wien bridge oscillator employing
an Op-Amp is limited by the:
(A) slew rate of the operational amplifier
(B) output offset voltage of the operational amplifier
(C) output offset current of the operational amplifier
(D) gain of the amplifier
In case of a phase shift oscillator, each RC circuit produces a phase shift of:
(A) 30°
(B) 60°
(C) 90°
(D) 180°

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31.	In e	very practical oscillator the loop gain is kept :
	(A)	exactly equal to the unity
	(B)	slightly less than unity
	(C)	slightly greater than unity
	(D)	not less than 10
32.	Iden	tify the true statement from the following:
	(A)	The input resistance in a voltage series feedback amplifier decreases
		while that in a voltage-shunt feedback amplifier increases
	(B)	The input resistance both in a voltage-series feedback amplifier and
8 8		voltage-shunt feedback amplifier decreases
	(C)	The input resistance both in a voltage-series feedback amplifier and
		voltage-shunt feedback amplifier increases
	(D)	The input resistance in a voltage-series feedback amplifier increases
		while that in a voltage-shunt feedback amplifier decreases
33.	The	temperature coefficient of resistance in case of semiconductors is :
	(A)	zero
357	(B)	infinity
	(C)	positive
	(D)	negative
34.	The	Fermi energy level in case of intrinsic semiconductors lies :

- (A) halfway between the conduction and valance bands
- (B) within the valance band
- (C) within the conduction band
- (D) close to the bottom of the conduction band

35.	When a sinusoidal voltage of frequency 60 Hz is applied across the prima	ry
i	erminals of the transformer in case of full-wave rectifier, the lowest frequen	су
	lternating component across the load will have the frequency :	
	A) 30 Hz	
(6)	B) 60 Hz	
	C) 90 Hz	
	D) 120 Hz	
36.	The reverse leakage current I _{CBO} :	
	A) increases with increase in I _E	
	B) decreases with increase in temperature	
	(C) increases with increase in temperature	
	(D) decrease with increase in V _{CB}	
37.	In case of RC coupled amplifier the main component which results in decrea	ıse
	in its gain in low frequency range :	
	(A) is coupling capacitor	
	(B) are the junction capacitances	
	(C) is the emitter resistance	
	(D) is emitter resistance bypass-capacitor	
38.	In case of class-A operation of an amplifier the output current flows fo	r:
	(A) full cycle	
8	(B) less than full cycle but more than half cycle	
	(C) half cycle	

(D) less than half cycle

- 39. The maximum efficiency of class-B operation will not exceed :
 - (A) 25%
 - (B) 50%
 - (C) 60.5%
 - (D) 78.5%
- 40. The circuit shown in Fig. (6) is :

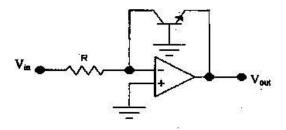


Fig. (6)

- (A) an integrator
- (B) a logarithmic amplifier
- (C) a differentiator
- (D) an adder
- 41. The Boolean expression for a two input A and B exclusive-OR gate is given

by:

- $(A) \quad f(A, B) = A + B$
- (B) f(A, B) = AB
- (C) $f(A, B) = \overline{A}B + A\overline{B}$
- (D) $f(A, B) = \overline{A} + B$
- 42. The Boolean expression $A + \overline{A}$ will always have logic value :
 - (A) 0
 - (B), A
 - (C) Ā
 - (D) 1

Electronics

- 43. The Boolean expression $A + \overline{A}B$ is equal to :
 - (A) AB
 - (B) A + B
 - (C) $\bar{A}B + A\bar{B}$
 - (D) A
- 44. The output Y in the circuit shown in Fig. (7) is given by :

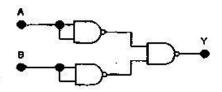


Fig. (7)

- $(A) \quad A + B$
- (B) AB
- (C) $\bar{A}B + A\bar{B}$
- (D) $(A + \overline{B})(\overline{A} + B)$
- 45. For 50 μA meter movement with a coil resistance of 200 Ω . What shunt resistance is required to extend the range to 250 μA ?
 - (A) 200 Ω
 - (B) 150 Ω
 - (C) 100 Ω
 - (D) 50 Ω

			a
46.			on index the ratio between the total power in the amplitude
	mod	ulated wave t	the unmodulated carrier power is given by:
	(A)	$m^2/2$	16
	(B)	$1 + m^2/2$	R
	(C)	$1 + m^2$	製

- (D) $(1 + m^2)/2$ 47. A carrier wave is simultaneously modulated by two sine waves with modulation indices of 0.3 and 0.4, the total modulation index is:
 - (A) 1.7
 - (B) 0.7
 - (C) 0.5
 - (D) 0.34
- 48. Identify the true statement from the following. In a superheterodyne receiver:
 - (A) a constant frequency difference is maintained between the local oscillator and the RF circuit
 - (B) no local oscillator is used
 - (C) a frequency difference equal to twice the intermediate frequency is maintained between local oscillator and RF circuit
 - (D) local oscillator frequency is normally double the IF
- 49. Identify the false statement from the following:
 - (A) FM has an infinite number of side bands.
 - (B) In FM the total transmitted power always remains constant with depth of modulation
 - (C) In FM the amplitude of the carrier component does not remain constant
 - (D) In FM with increased depth of modulation the required bandwidth is decreased

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50.	The image frequency of a superheterodyne receiver :
	(A) is not rejected by the IF tuned circuit
	(B) is produced within the receiver
	(C) is independent of the frequency to which the receiver is tuned
	(D) is due to the insufficient adjustment of channel receiver
51 .	The carrier wave $V_c = 80 \sin{(2 \times 10^6 t)}$ is amplitude modulated by a modu-
20	lating signal $V_m = 4 \sin (200t)$, the modulation index is:
	(A) 0.01
	(B) 0.05
	(C) 0.25
	(D) 0.50
52.	If δ and f_m represent the frequency deviation and modulating frequency the
	modulation index of FM is given by:
	(A) f_m/δ
	(B) δ/f_m
*	(C) δf_m
	(D) $\delta f_m/2$
53.	In case of frequency modulation :
	(A) the total number of side bands depend on the modulation index
	(B) the carrier frequency cannot disappear
	(C) the amplitude of any side band does not depend on the modulation
	notaring and and area area area area area area industring area.

the amplitude of any side band depends on the modulation index

14

(D)

Electronics

54.	In C-programming the while (expression) statement is used to carry out
	looping operation. The included statements will executed repeatedly as long
	as the value of the expression is:

- (A) zero
- (B) one only
- (C) negative
- (D) not zero.
- 55. In C-programming the expression ++k is equivalent to :
 - (A) k=k+1+1
 - (B) k=k-1
 - (C) k=k+1
 - (D) k=k+k
- 56. In C-programming the global variables are the variables defined :
 - (A) inside the function program
 - (B) outside the main program
 - (C) inside the main program
 - (D) in function declaration statement
- 57. Identify the false statement from the following:
 - (A) A pointer is a variable which holds the memory address of another variable.
 - (B) A pointer allows to return structured variables from a function
 - (C) A pointer allows to pass variables, arrays, functions, strings and structures to a function arguments
 - (D) A pointer does not support dynamic allocation and deallocation of memory segments

58.	Identify	the	false	statement.	In	C-programming	:
-----	----------	-----	-------	------------	----	---------------	---

- (A) all processor directives begin with the sharp sign #
- (B) the processor directive is terminated by a semicolon
- (C) only one processor directive can occur in a line
- (D) the processor directive may appear at any place in source file
- 59. The electromagnetic wave when travelling through the free space will suffer only one of the following:
 - (A) Reflection
 - (B) Refraction
 - (C) Attenuation
 - (D) Absorption
- 60. The highest frequency that will return to earth by a given atmospheric layer after being beamed straight up at it is known its:
 - (A) critical frequency
 - (B) maximum useable frequency
 - (C) window
 - (D) resonant frequency

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In case of amplitude modulation if three sine waves simultaneously modulate the carrier with individual modulation indices m_1 , m_2 and m_3 , then total modulation index is given by:

(A)
$$\sqrt{m_1^2 + m_2^2 + m_3^2}$$

(B)
$$m_1 + m_2 + m_3$$

(C)
$$\sqrt[3]{m_1 m_2 m_3}$$

(D)
$$(m_1 + m_2 + m_3)/2$$

Identify the false statement with regard to advantages and disadvantages of FM:

- (A) FM is, or can be made, relatively immune to the effects of noise
- (B) A much smaller channel is required by FM, up to 1/10 times as small as that needed by AM
- (C) FM transmitting and receiving equipments tend to be more complex
- (D) The amplitude of the FM wave is constant. It is thus independent of modulation index

3. The absorption of radio waves by the atmosphere depends on :

- (A) the distance from the transmitter
- (B) the polarization of the wave
- (C) the frequency of the wave
- (D) both the distance and the polarization of the wave

4. The most suitable method out of the following in measurement of the resistance of expected value less than 1 Ω is :

- (A) Limit bridge method
- (B) Wheatstone's bridge method
- (C) Loss of charge method
- (D) Kelvin's bridge method

- 5. The diffusion current density is:
 - (A) directly proportional to the concentration gradient of charge carriers
 - (B) inversely proportional to the concentration gradient of charge carriers
 - (C) independent of the concentration gradient of charge carriers
 - (D) directly proportional to concentration of charge carriers
- 6. With increase in temperature:
 - (A) the resistivity of a conductor decreases while that of a semiconductor increases
 - (B) the resistivity of both conductor and semicodnuctor increases
 - (C) the resistivity of both conductor and semiconductor decreases
 - (D) the resistivity of a conductor increases and that of semiconductor decreases
- 7. The ratio of electron and hole concentrations in case of an intrinsic semiconductor is:
 - (A) greater than one
 - (B) less than one
 - (C) equal to one
 - (D) equal to square of the intrinsic carrier concentration

Electr.

- 8. In case of a centre-tap full-wave rectifier if $V_{\rm max}$ is the peak voltage across the secondary of the transformer, the voltage appearing across the non-conducting diode is :
 - (A) V_{max}
 - (B) 2 V_{max}
 - (C) √2V_{max}
 - (D) $V_{max}/\sqrt{2}$
- 9. In common base configuration if I_E is the emitter current and α is the current gain, the part of the emitter current which forms the collector current is :
 - (A) αI_E
 - (B) $(1 \alpha)I_R$
 - (C) $(1-\alpha)I_E + \alpha$
 - (D) $(1 + \alpha)I_E$
- 10. The configuration having the highest input resistance, lowest output resistance and voltage gain less than unity is:
 - (A) CE
 - (B) CC
 - (C) CB
 - (D) Both CE and CB
- 11. The graph plotted between the drain current I_D and gate-source voltage V_{GS} for a given drain source voltage V_{DS} of a MOSFET is called its :
 - (A) output characteristics
 - (B) input characteristics
 - (C) transfer characteristics
 - (D) load line

12.	The p	process used in growing thin layers of the material on the semiconductor
	surfa	ce in fabrication of the semiconductor devices is known as:
	(A)	Lithography
	(B)	Metallization
	(C)	Diffusion
	(D)	Epitaxy
13.	The	operation of N-channel JFET involves flow of :
	(A)	electrons
	(B)	holes
	(C)	both electrons and holes
	(D)	doping impurity ions
14.	The	principle of superposition is a fundamental consequence of:
	(A)	non-linearity
	(B)	linearity
	(C)	reciprocity
	(D)	both non-linearity and reciprocity
15.	The	branch relationship of a two terminal resistive element is linear if
	it is	:
	(A)	homogeneous
	(B)	additive
	(C)	homogeneous and additive
	(D)	none of the above
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	13. 14.	surfa (A) (B) (C) (D) 13. The (A) (B) (C) (D) 14. The (A) (B) (C) (D) 15. The it is (A) (B) (C) (D)

16.	in	model analysis of networks the choice of a reference node:	
	(A)	alters the currents flowing through its branches	
	(B)	effects the operation of the network	
	(C)	alters the voltage across the elements	
	(D)	affects the voltage of various nodes	
17.	The	drain-source voltage at which the channel opening of a JFET reduc-	es
	to z	ero is known as :	
	(A)	cut-in voltage	
	(B)	punch-through voltage	
	(C)	pinch-off voltage	
	(D)	breakdown voltage	
18.	The	quality factor of any circuit is given by :	
	(A)	2π times the energy dissipated per cycle divided by the energy store	ed
		per cycle	
	(B)	2π times the energy stored per cycle divided by the energy dissipate	d
		per cycle	
	(C)	2π times the energy stored per cycle	
	(D)	2π times the energy dissipated per cycle	
Electr.	ă	5 P.T.O).

19.	The	normal binary code of Gray 11011 is:
	(A)	11111
	(B)	11110
	(C)	11010
	(D)	10010
20.	At r	esonance frequency w, the Q of a series LCR circuit is given by:
	(A)	ωL/R
	(B)	ωC/R
	(C)	R/ωL
	(D)	ω/RL
21,	A de	vice said to be active if its I-V characteristic lies in the :
	(A)	1st quadrant
	(B)	2nd and 4th quadrants
	(C)	1st and 3rd quadrants
	(D)	3rd quadrant
22.	The t	threshold voltage of p-channel enhancement MOSFET is :
	(A)	zero
	(B)	positive
	(C)	negative
	(D)	independent of device geometry

Electr,

23	3	$\frac{b}{a^2 + as + b}$ is a second order filter gain function that realizes the
	cl	laracteristics of a :
	(A	
	(E	
	(C	
	Œ	
24.	Ide	entify the false statement from the following. The RC filters offer :
	(A)	increased circuit reliability because 5
		increased circuit reliability because for all the processing steps can be automated
	(B)	improvement in performance because high quality components can be realized
	(C)	an increase in parasitic
	(D)	simpler design process
25.	The	frequency response curve of a first order filter rolls-off at a rate of :
8	(A)	10 db/decade
	(B)	20 db/decade
	(C)	10 db/octave
	(D)	20 db/octave
26.	The	total number of sets of input conditions that will produce a high output
	from	a three-input OR gate is :
	(A)	
	(B)	8
	(C)	15
	(D)	16
Electr.		

P.T.O.

27.	The	logic expression $\overline{\overline{A} + B} + \overline{\overline{A} + \overline{B}}$ on simplification reduces to :
	(A)	A + B
	(B)	A
	(C)	AB
	(D)	В
28.	A N	AND gate with all inputs connected together will function as:
	(A)	OR gate
	(B)	AND gate
	(C)	NOT gate
	(D)	NOR gate
29.	Acco	rding to De Morgan's theorem :
	(A)	the complement of the product of two or more variables is equal to the
		sum of the variables
	(B)	the complement of the product of two or more variables is equal to the
	i.	product of the variables
	(C)	the complement of the product of two or more variables is equal to the
		product of the complements of the variables
	(D)	the complement of the product of two or more variables is equal to the
		sum of the complements of the variables
Electr.	9	8

30.	When	2's complement of a binary number is taken twice, the result	will
	be:		
	(A)	square of the original number	
	(B)	double of the original number	
	(C)	original number	
	(D)	half of the original number	
31.	Wher	binary number 1110101 is divided by the number 1001, the re	esult
	is :		
	(A)	1001	
	(B)	1101	
	(C)	1010	
	(D)	0101	
32.	In Sci	hottky TTL families a Schottky diode clamping between base and coll	ector
	of the	e transistor is used to :	
	(A)	prevent transistor saturation	
	(B)	prevent transistor breakdown	
	(C)	prevent short circuit failure	
	(D)	increase the fan-in	
33.	Identify the false statement. Excess-3 code:		
	(A)	is an unweighted code	
	(B)	is used in representing a alphanumeric data	
	(C)	is a self-complementing code	
	(D)	uses only 10 of the 16 possible 4-bit code groups	
Electr.	83	9 P	.T.O.

- 34. In logic circuits the positive logic is one in which:
 - (A) logic 0 and logic 1 are represented by negative and positive voltages respectively
 - (B) logic 0 and logic 1 are represented by zero and positive voltages respectively
 - (C) the voltage corresponding to logic 0 is lower than that corresponding to logic 1
 - (D) the voltage corresponding to logic 0 is higher than that corresponding to logic 1
- 35. With a NAND RS-latch a low R and low S produces:
 - (A) high output
 - (B) low output
 - (C) no change
 - (D) race condition
- 36. A multivibrator which continuously switches between two quasi-stable states without external excitation is known as:
 - (A) bistable multivibrator
 - (B) monostable multivibrator
 - (C) astable multivibrator
 - (D) flip-flop

	(A)	0	
	(B)	1	
	(C)	A	
	(D)	Ā	
38.	The	minimum number of JK flip-flops required for designing a modulus-10	
	counter is:		
	(A)	4	
	(B)	6	
	(C)	8	
	(D)	10	
39.	Iden	tify the correct statement from the following:	
	(A)	Static RAM is volatile while dynamic RAM is non-volatile	
	(B)	Static RAM is non-volatile while dynamic RAM is volatile	
	(C)	Both static and dynamic RAM are volative	
	(D)	Both static and dynamic RAM are non-volatile	
40.	Dyn	amic RAM :	
	(A)	uses bipolar or MOS flip-flop	
	(B)	uses MOSFET's and capacitors	
	(C)	needs no refreshing of the data	
	(D)	contains less memory cells than a static RAM on the same chip area	
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The logical value of the logical function A + A is :

37.

41.	The	8085 A microprocessor has:
	(A)	10 restart instructions
	(B)	8 restart instructions
	(C)	6 restart instructions
	(D)	4 restart instructions
42.	The	execution of RST2 instruction vectors to location:
	(A)	0000 _H
	(B)	0008 _H
163	(C)	0010 _H
	(D)	0018 _H
43.	The	hardware restart of 8085A microprocessor which has the highest priority
	and	when active branches the program to location 0024 _H is:
	(A)	RST 7.5
	(B)	RST 6.5
	(C)	RST 5.5
	(D)	Ттар
44.	The	decrease in gain of an RC coupled amplifier at low frequency is mainly
	due to:	
	(A)	junction capacitances of the transistor
	(B)	emitter resistance
	(C)	coupling capacitor
	(D)	voltage divider resistances used for self-biasing of the amplifier
Electr		12

- 45. If R_i and R_o are the input and output resistances of an amplifier, its power gain in decibels equals its voltage gain in decibels when :
 - (A) $R_i = 2R_o$
 - (B) $R_i = R_o$
 - (C) $R_i = R_0/2$
 - (D) $R_i = 5R_o$
- 46. A phasor is :
 - (A) a vector representing the magnitude and phase of an alternating quantity
 - (B) graph representing the frequency and phase of an amplifier
 - (C) an instrument used for determination phase difference between two time varying quantities
 - (D) a colour tag for distinguishing between different phases of 3-phase supply
- 47. When the output flows for less than one-half cycle of the input signal, the amplifier is said to operate in :
 - (A) Class-A mode
 - (B) Class-AB mode
 - (C) Class-B mode
 - (D) Class-C mode

48.	If an amplifier has an overall current gain of 200 and input resistance of			
	20 k Ω with a load resistance of 10 k Ω . The overall voltage gain of the			
	amplifier is :			
	(A) 20 dB			
28	(B) 40 dB			
	(C) 60 dB			
	(D) 80 dB			
49.	Two amplifiers having mid band voltage gains 20 dB and 40 dB are connected			
	in cascade. The overall voltage gain of the cascade configuration			
	will be:			
	(A) 800 dB			
	(B) 60 dB			
	(C) 30 dB			
	(D) 2 dB			
50.	A class-B push-pull amplifier suffers from:			
	(A) intermodulation distortion			
	(B) excess harmonic distortion			
	(C) cross-over distortion			
	(D) none of the above			
51.	An amplifier with a voltage gain of 1000 uses 1/100th of its output in negative			
	feedback, the gain with feedback is:			
	(A) 90.9			
	(B) 80.9			

(C)

(D)

20.9

10.9

ter variable can be assigned a null (zero) value
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ter variable can be assigned the value of another poi
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e ter variable can be assigned the address of an ordin
eger quantity cannot be added to or subtracted from a poi
false statement from the following:
6-7
of the following operators does not belong to unary oper
ridge
bridge
stone bridge
ng bridge
following bridges which one is used for determination
er
ing machine language program as output is called :
li

- 56. If i = 1, then on execution of ++i statement the value of i will be:
 - (A) 1
 - (B) 2
 - (C) 3
 - (D) 4
- 57. Identify false statement. In C programming:
 - (A) a process directive may appear at any place in a source file
 - (B) only one processor directive can occur in a line
 - (C) a processor directive is terminated by a semicolon
 - (D) all processor directives begin with the sharp sign (#)
- 58. In C programming when working with stream-oriented data file, one has to establish first a buffer area. This is accomplished by:
 - (A) fwrite
 - (B) fopen
 - (C) fclose
 - (D) FILE
- 59. Which of the following operators enjoys the highest precedence in C programming?
 - (A) Unary operators
 - (B) Logical operators
 - (C) Relational operators
 - (D) Arithmetic operators
- 60. Idetnify the false statement from the following:
 - (A) A Union contains members whose individual data types may differ from one another
 - (B) The members that compose a union each are assigned its unique storage area within the computer's memory
 - (C) The members that compose a union all share the same storage area within the computer's memory
 - (D) A union can be member of a structure and a structure can be a member of a union.